

Tunable Coherent Optical Sources for Gamma-Ray Generation

Majid Ebrahim-Zadeh

***ICFO, Institut de Ciències Fotoniques
Jordi Girona 29, Nexus II, 08034 Barcelona, Spain***

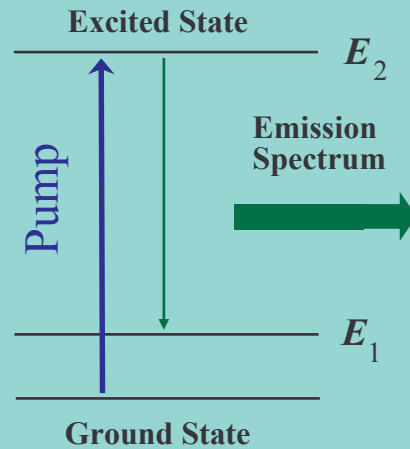
***Tel: 0034-93-413 7911
Fax: 0034-93-413 7943
E-mail: majid.ebrahim@icfo.es
www.icfo.es / www.icrea.es***

***Barcelona
28 de Octubre de 2004***

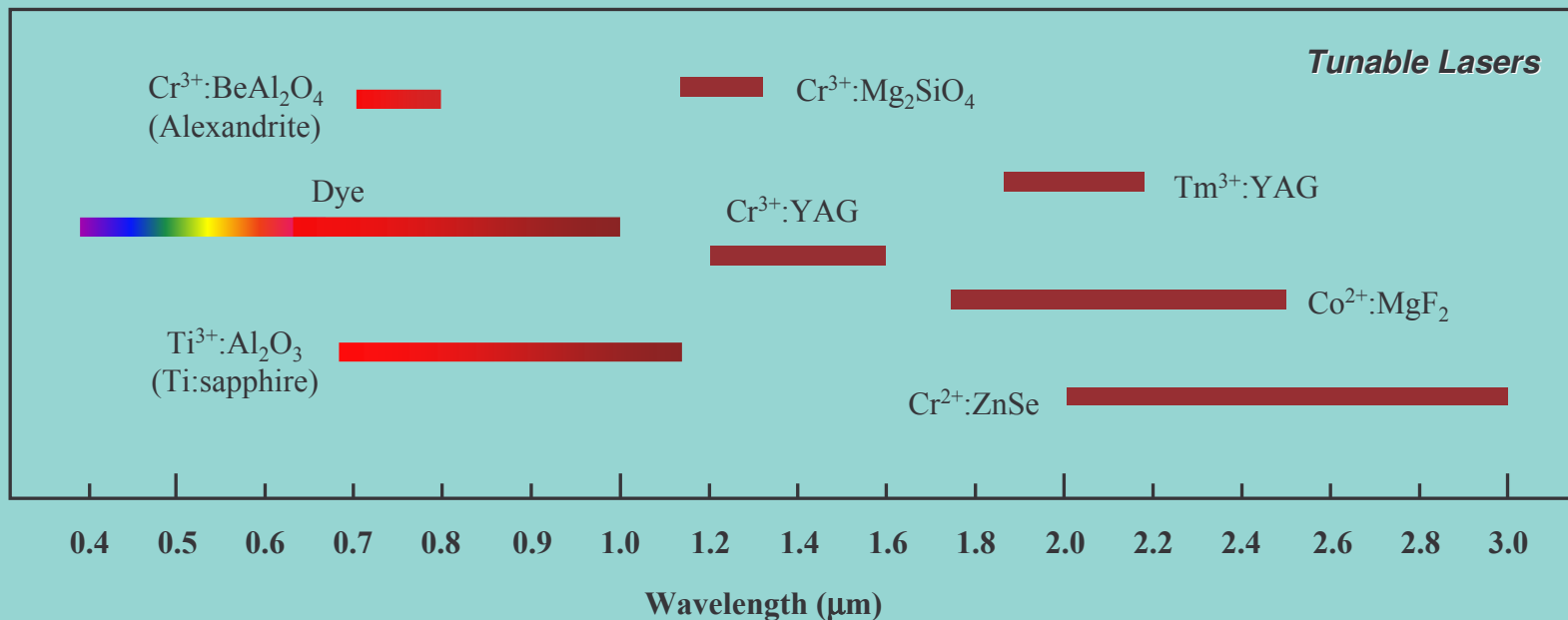
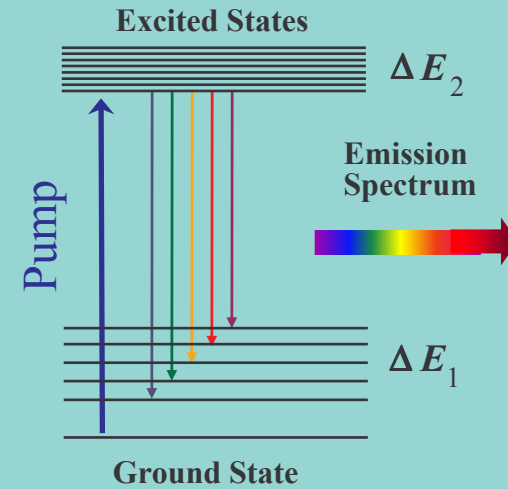
- *The Laser*
- *Optical Parametric Oscillator (OPO)*
- *OPO Advantages*
- *OPOs for γ -Ray Generation*
- *Device Formats*
- *Costs*
- *Conclusions*

The Laser

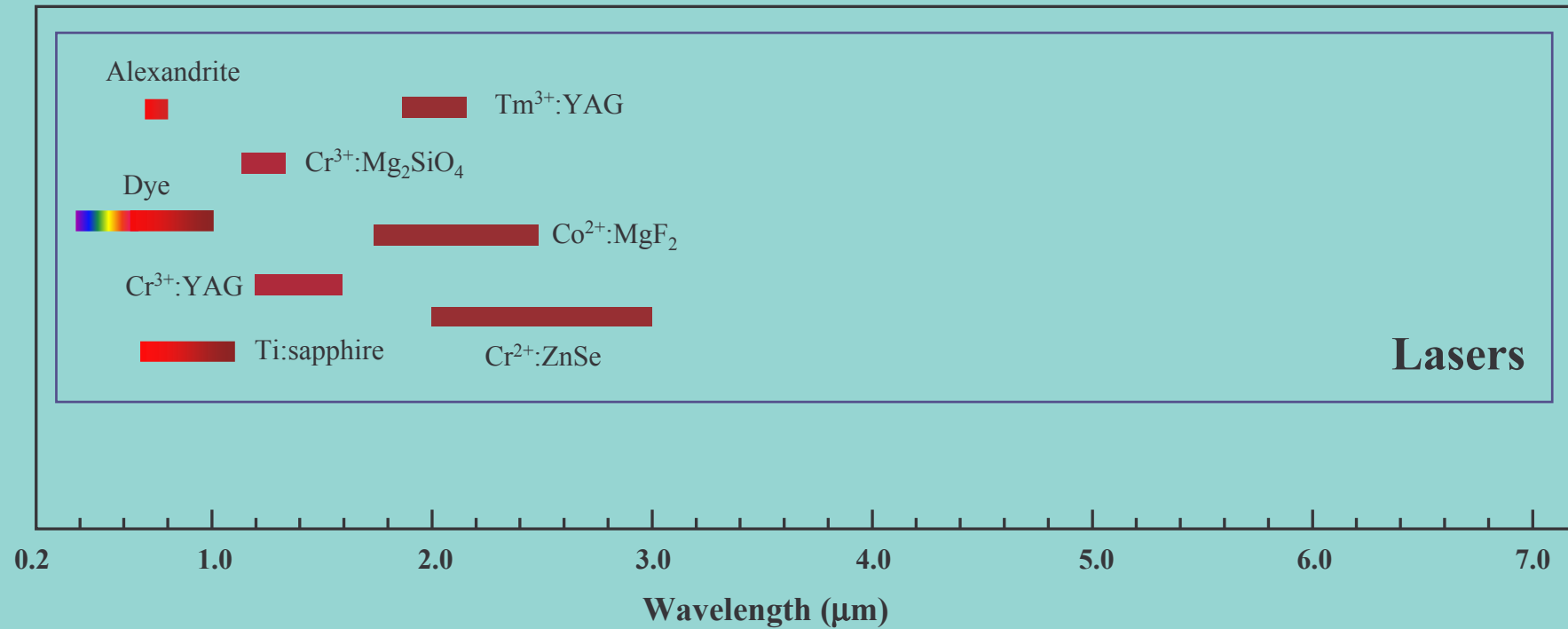
“Traditional” Laser



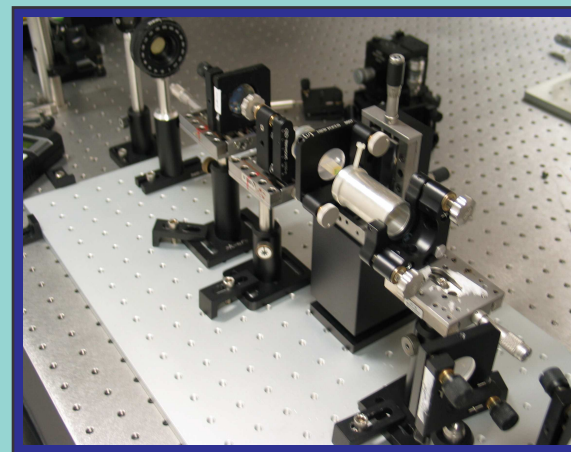
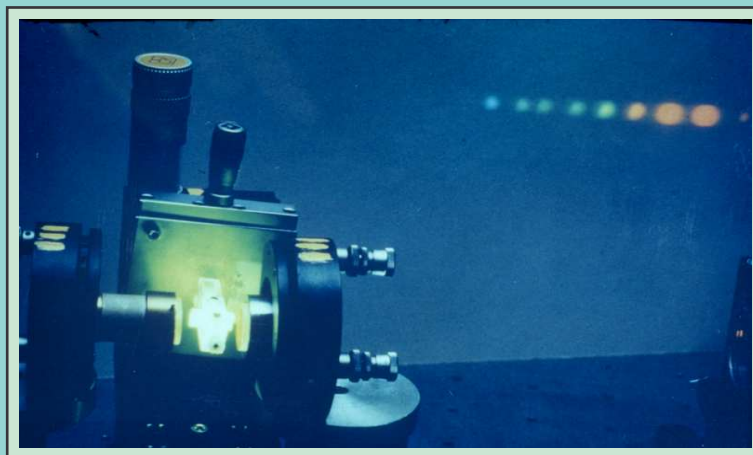
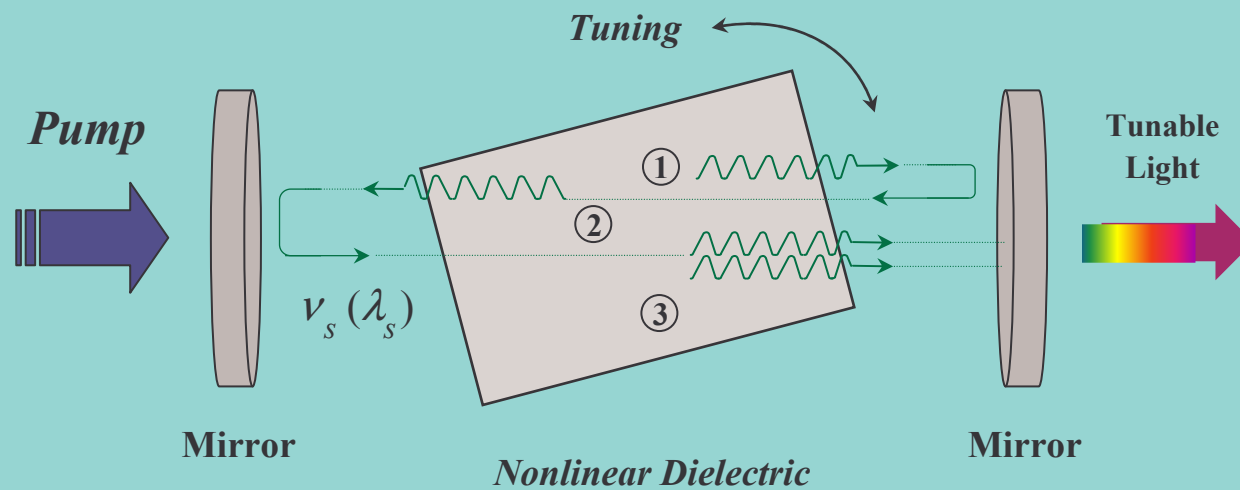
“Tunable” Laser



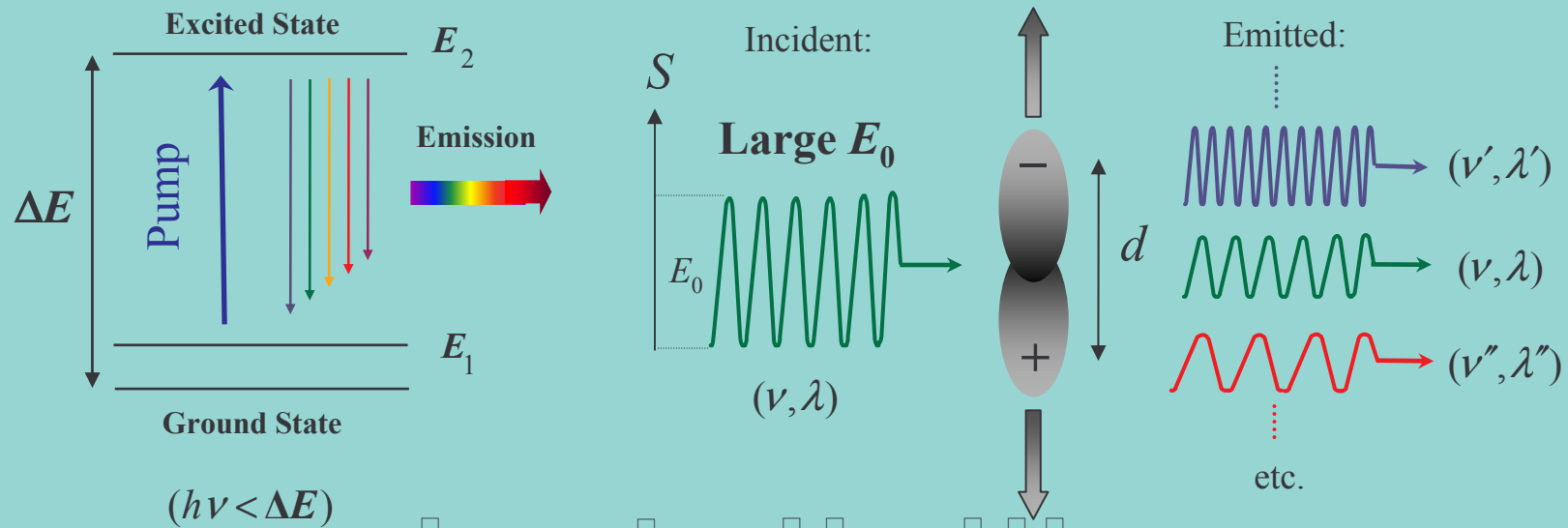
Spectral Coverage



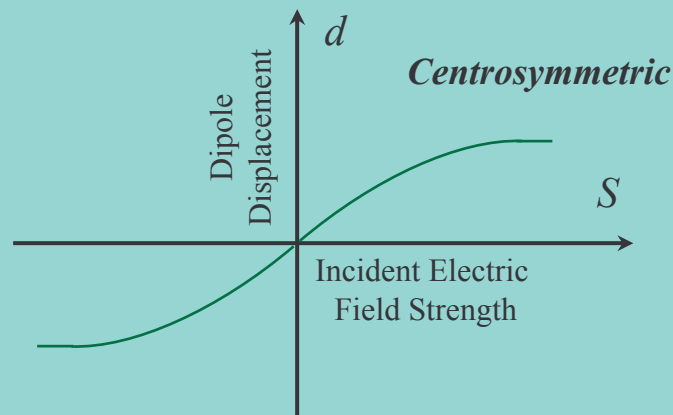
Optical Parametric Oscillator (OPO)



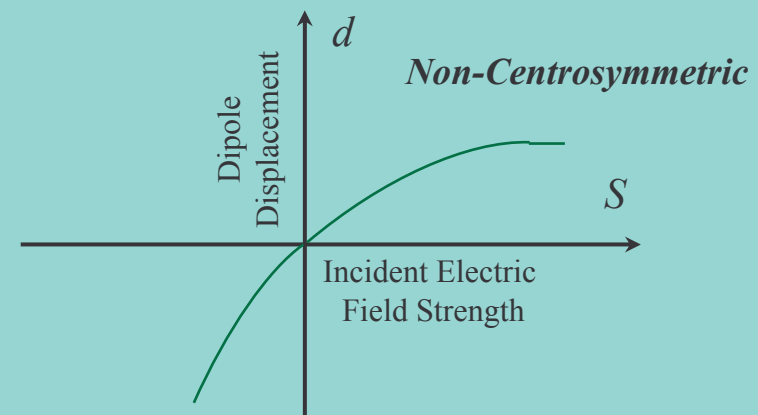
Operating Principle



$$\mathbf{P} = \epsilon_0 \left[\chi^{(1)} \cdot \mathbf{E} + \chi^{(2)} \cdot \mathbf{E} \cdot \mathbf{E} + \chi^{(3)} \cdot \mathbf{E} \cdot \mathbf{E} \cdot \mathbf{E} + \dots \right]$$

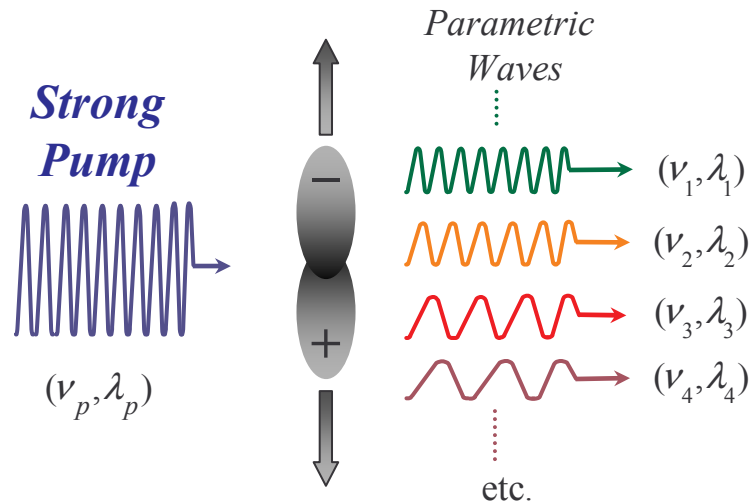


$$\mathbf{P} = \epsilon_0 \left[\chi^{(1)} \cdot \mathbf{E} + \chi^{(3)} \cdot \mathbf{E} \cdot \mathbf{E} \cdot \mathbf{E} + \dots \right]$$

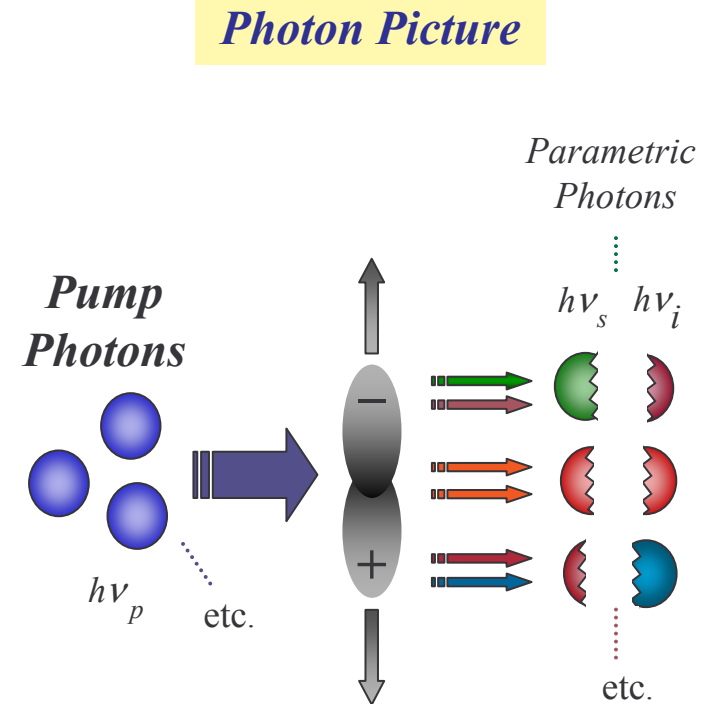


$$\mathbf{P} = \epsilon_0 \left[\chi^{(1)} \cdot \mathbf{E} + \chi^{(2)} \cdot \mathbf{E} \cdot \mathbf{E} + \chi^{(3)} \cdot \mathbf{E} \cdot \mathbf{E} \cdot \mathbf{E} + \dots \right]$$

Optical Parametric Generation

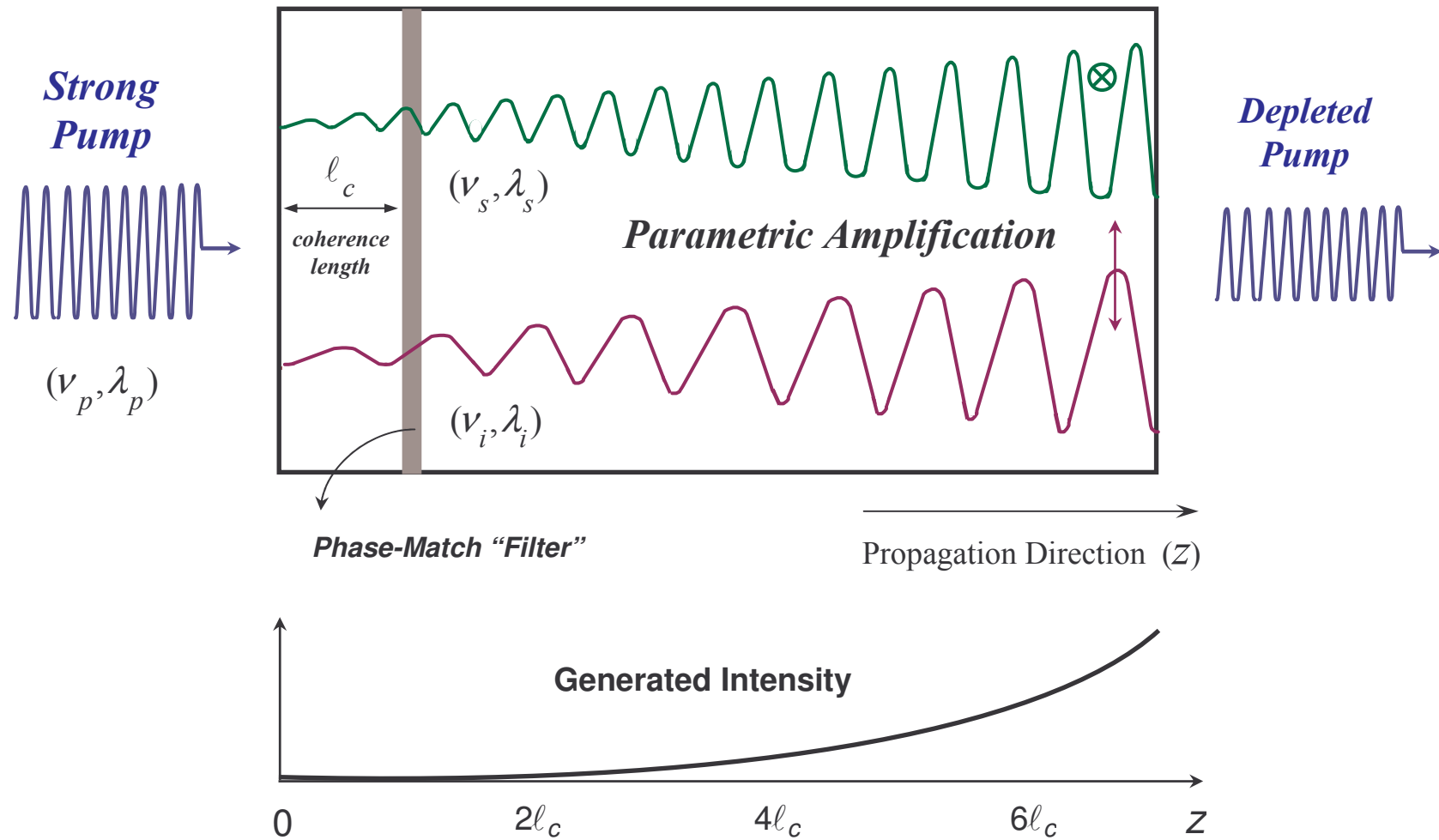


Wave Picture

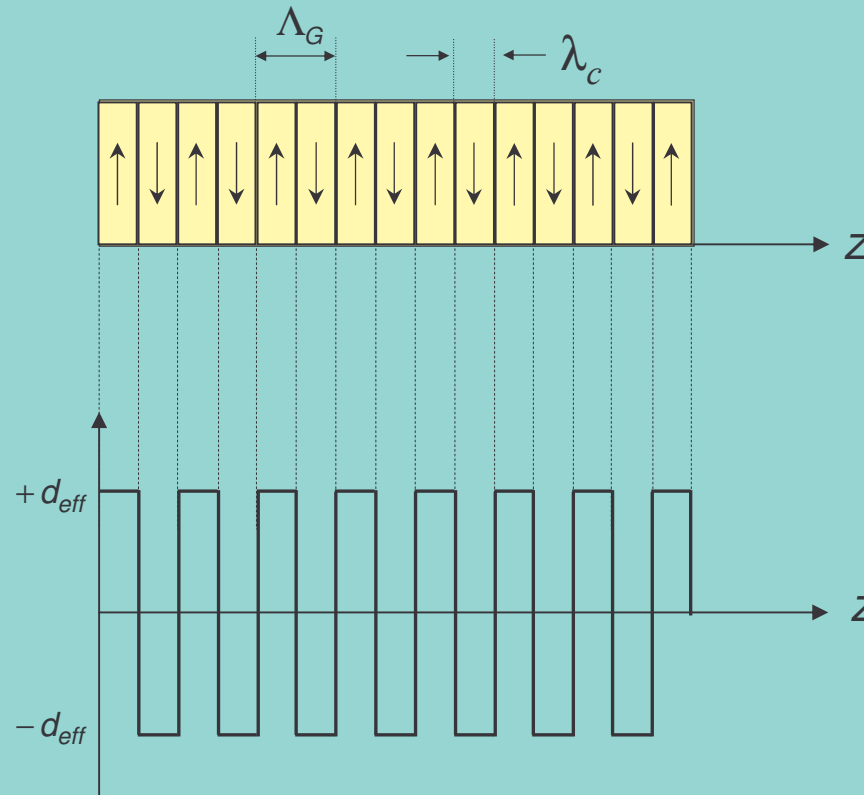


Birefringent Phase-Matching

Nonlinear Material : **Anisotropic**



Quasi-Phase-Matching



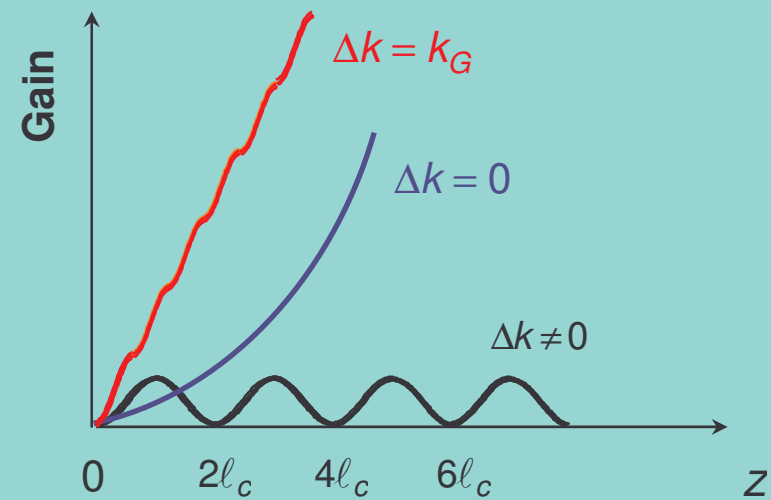
$$d_{eff}(\text{QPM}) = \left(\frac{2}{m\pi} \right) d_{eff}$$

$$\Delta k \rightarrow \Delta k_Q = k_3 - k_2 - k_1 - k_G$$

Phase-Match
Condition:

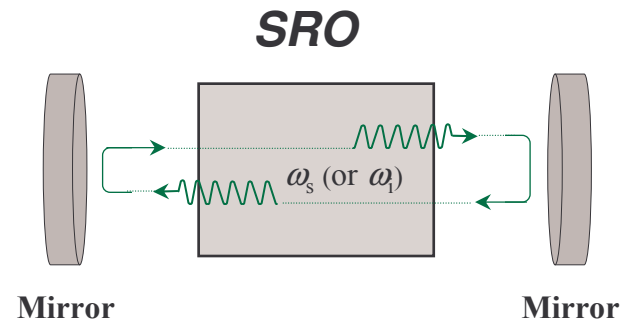
$$\Delta k_Q = k_3 - k_2 - k_1 - k_G = 0$$

$$k_G = 2\pi / \Lambda_G$$

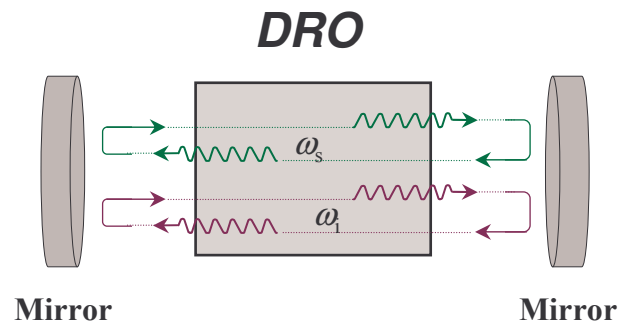


OPOs: Basic Resonance Configurations

Singly Resonant Oscillator

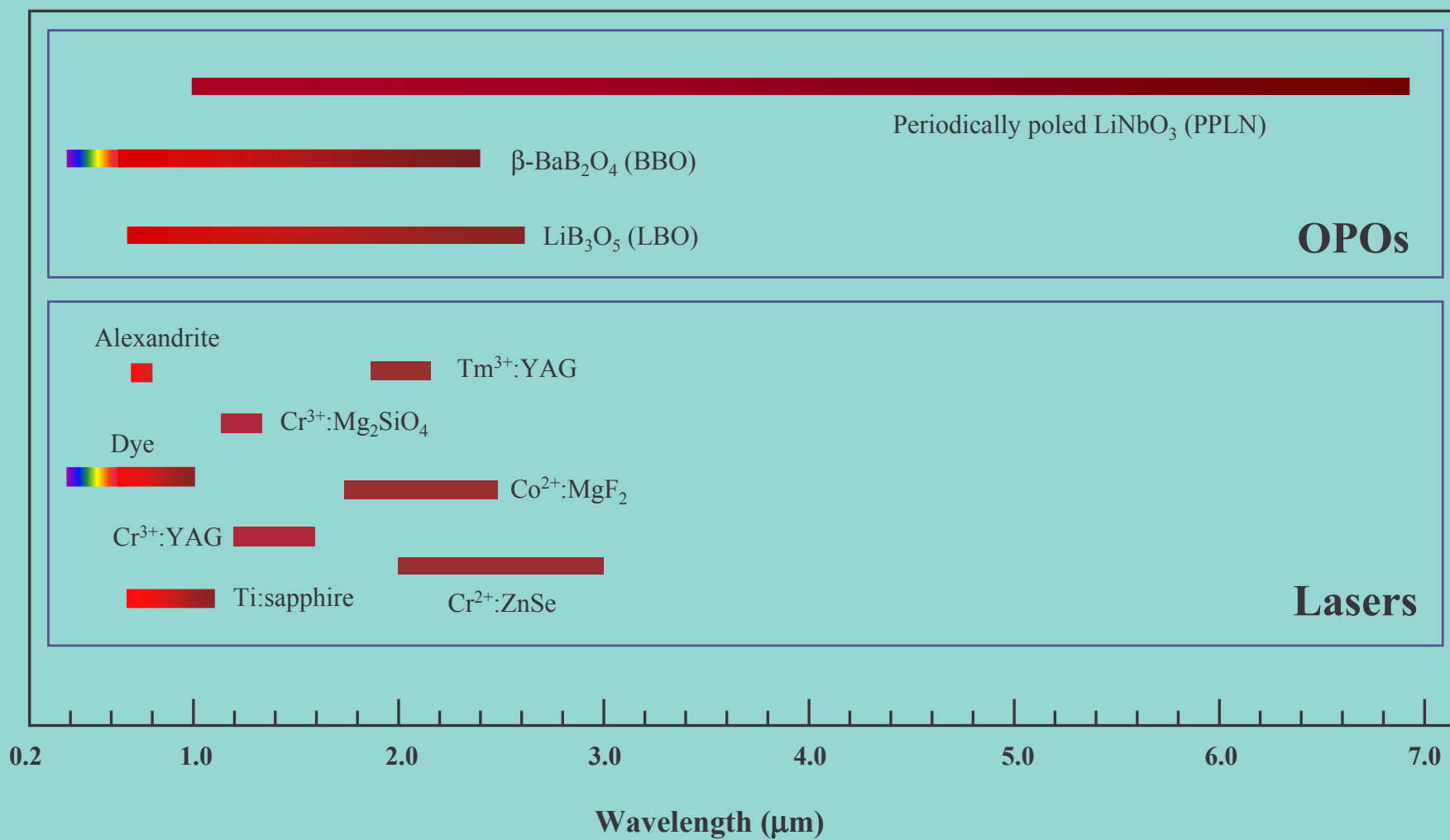


Doubly Resonant Oscillator



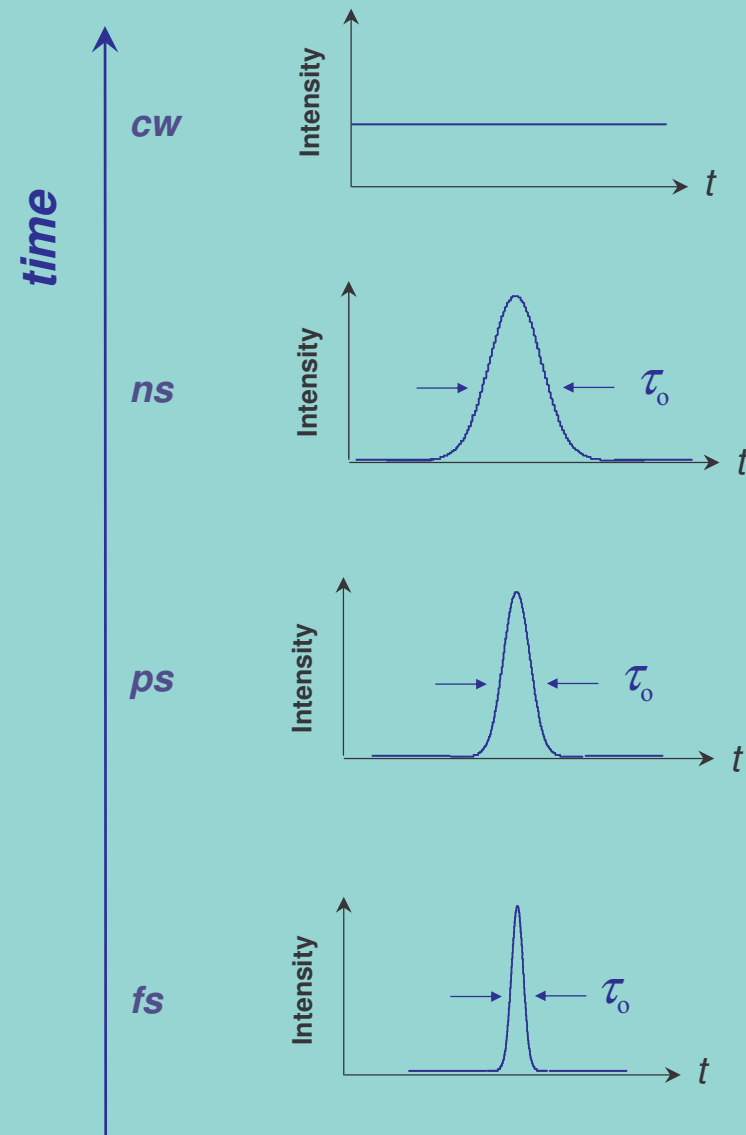
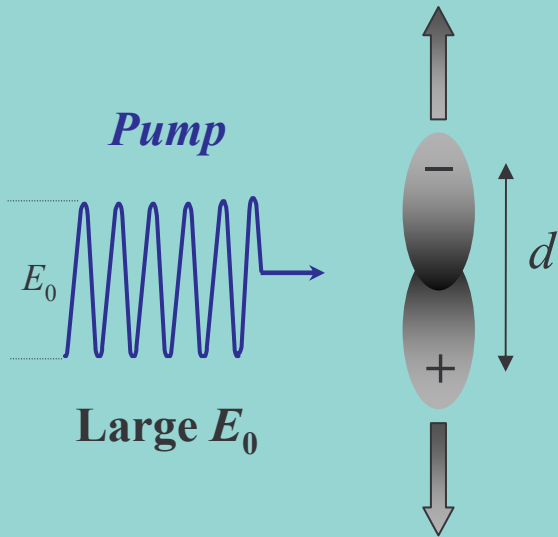
OPO Advantages

Spectral Versatility



Electronic Susceptibility

($\ll 10^{-15}$ seconds)



Optical Parametric Oscillators (OPOs)

- **Wavelength Versatility:** Ultraviolet $\longrightarrow$ Mid-Infrared / THz
- **Temporal Versatility:** CW $\longrightarrow$ Femtosecond
- **Operation:** > Room Temperature
- **High Powers / Energies:** 30 W, 200 mJ
- **High Efficiencies:** Typically > 50%
- **Compact, All-Solid-State Design**

Nonlinear Materials

- Birefringent:
(BBO, LBO, KTP, ZGP,...)
- **Quasi-Phase-Matched**
(PPLN, PPKTP, PPRTA,..)



Laser Sources

- Crystalline
- Semiconductor
- Fiber



Device Innovations

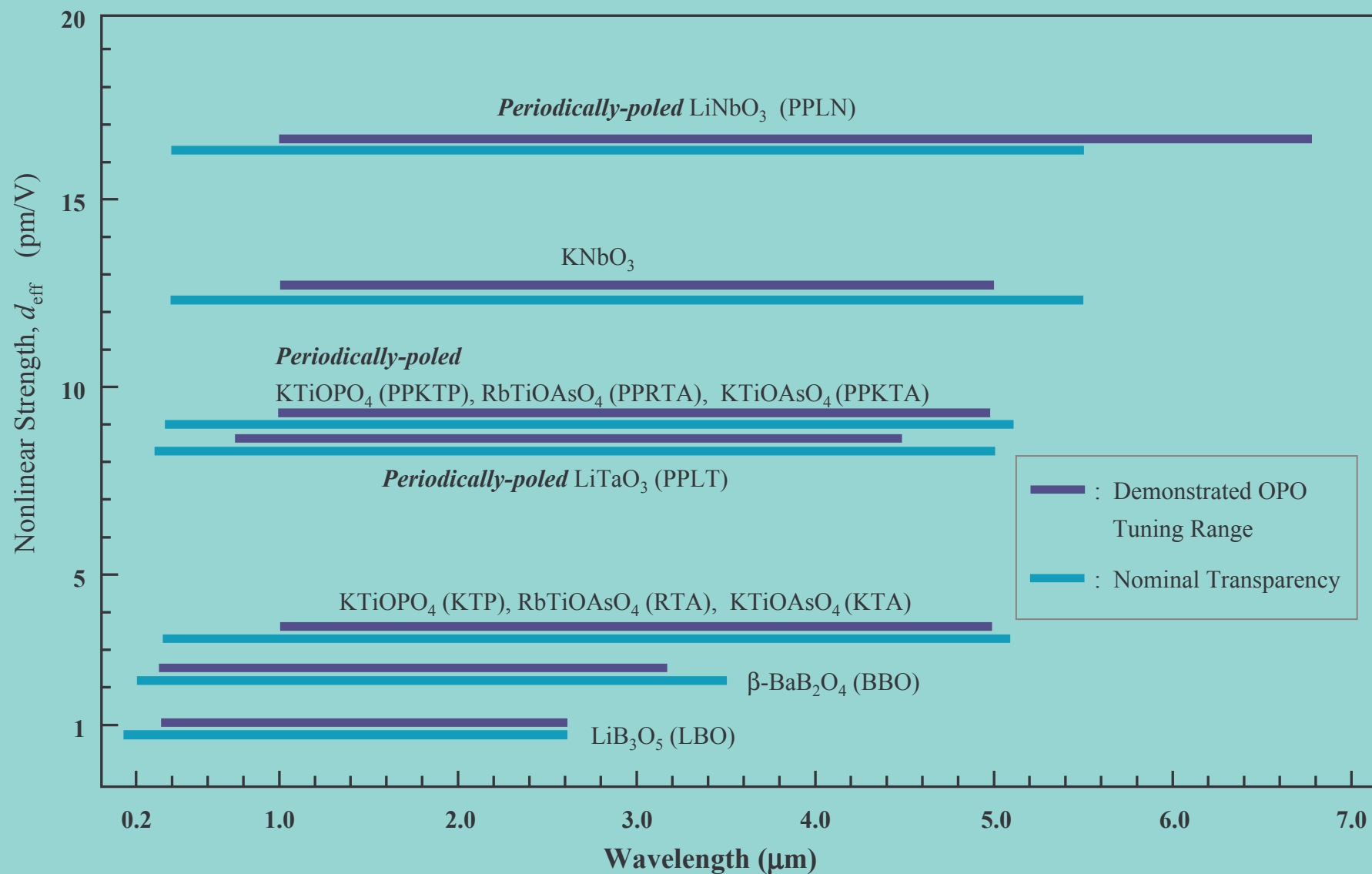
- Intracavity
- Pump-Resonant
- Dual-Cavity, etc.



New Generation of OPO Devices

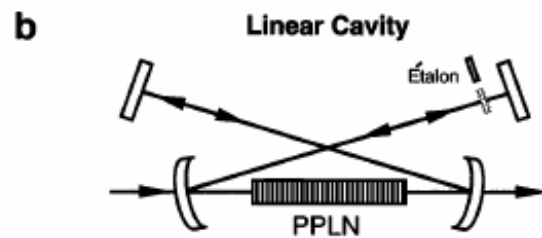
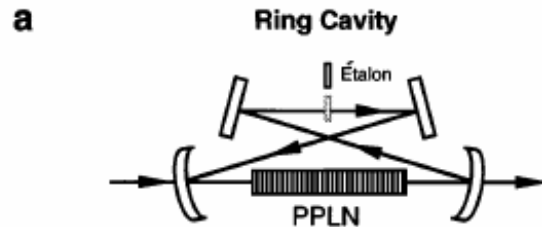
- Low-Threshold, Low-Power (mW) → High-Threshold, High-Power (Watts)
- CW → Femtosecond; nJ → mJ; Hz → GHz
- High Spatial and Spectral Coherence; High Frequency Stability
- Exceptional Tunability (Coarse and Fine)
- High Efficiency (>50%)
- Compact; All-Solid-State
- Novel Applications

New Nonlinear Materials

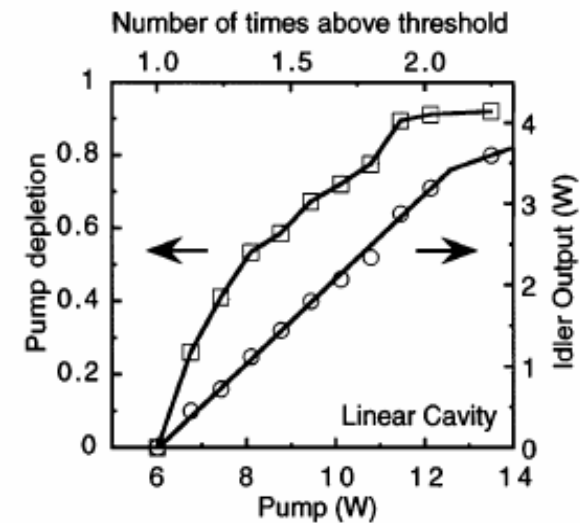
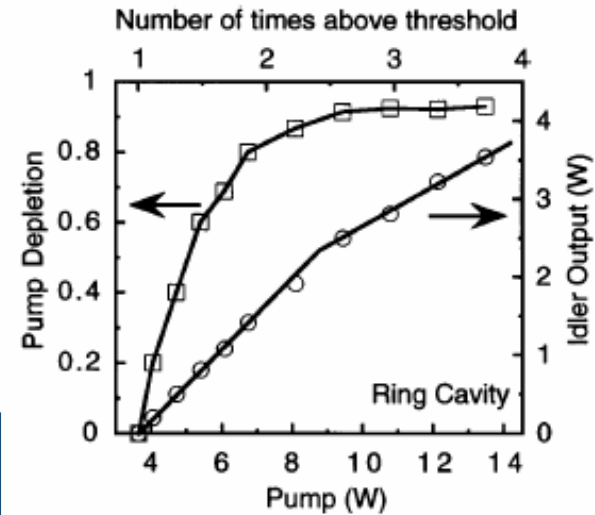
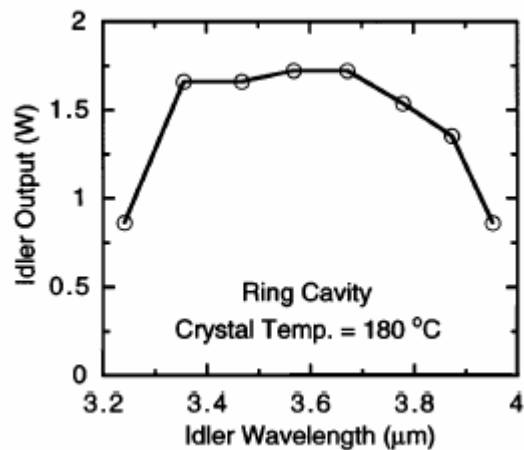


Device Formats

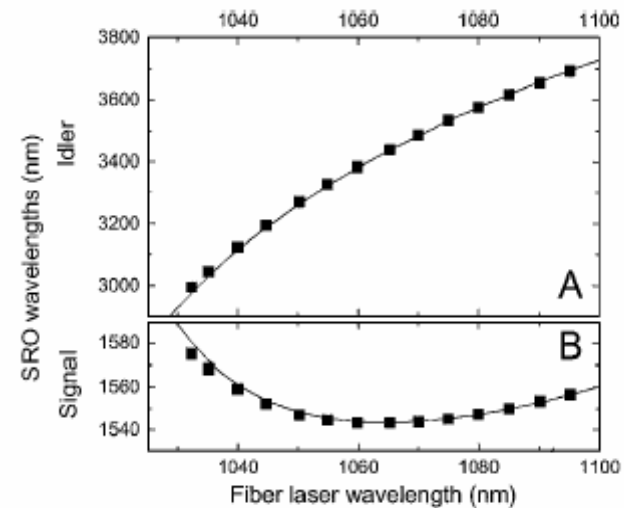
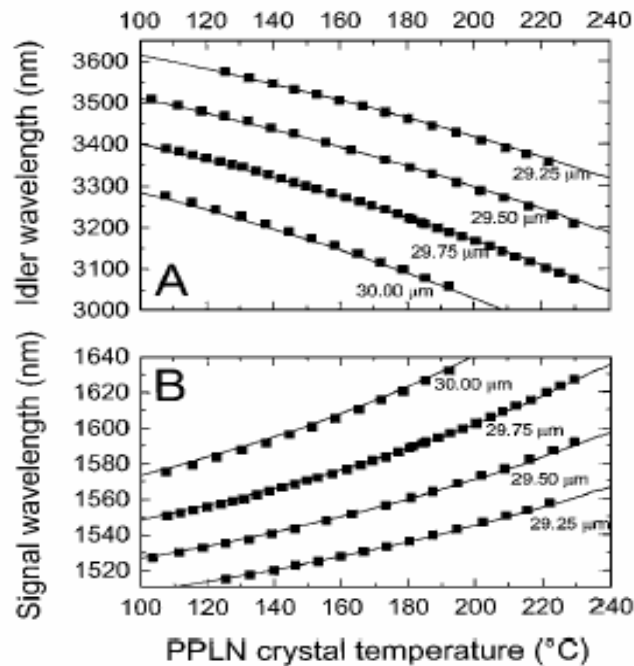
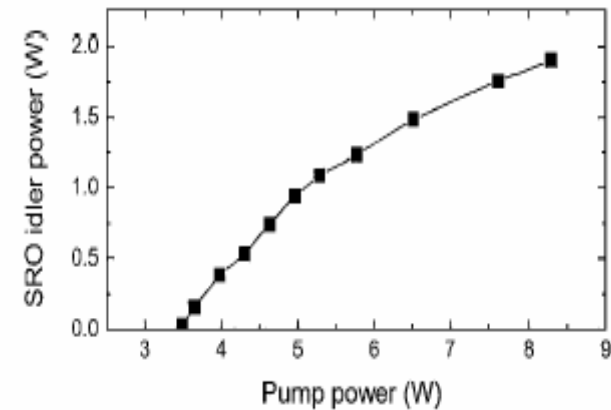
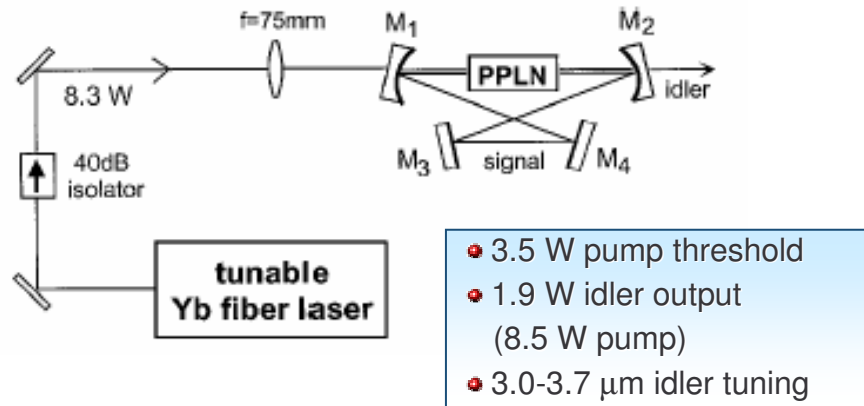
High-Power CW OPO



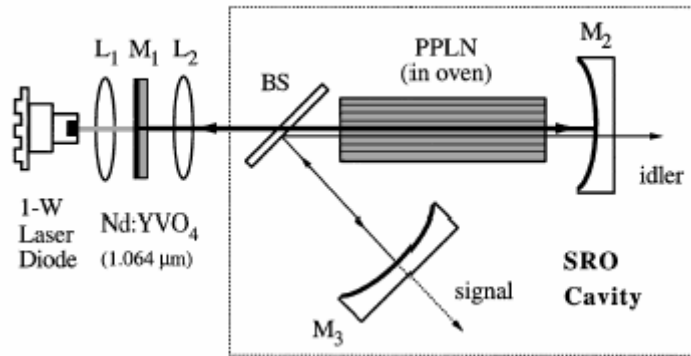
- $P_{th} \sim 4-6$ W
- $P_{idler} \sim 3.5$ W
(8.5 W pump)
- $\lambda_{idler} \sim 3-4$ μm



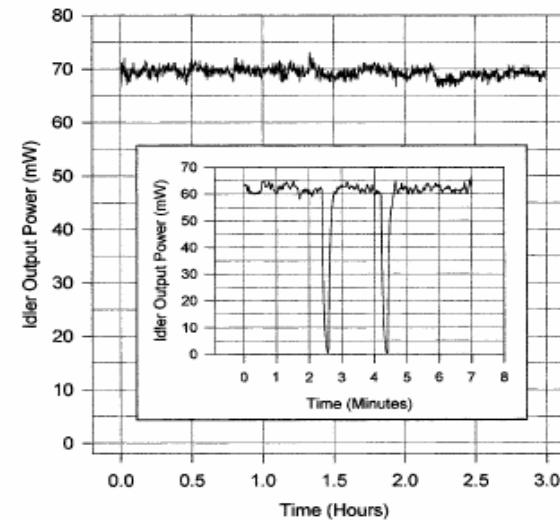
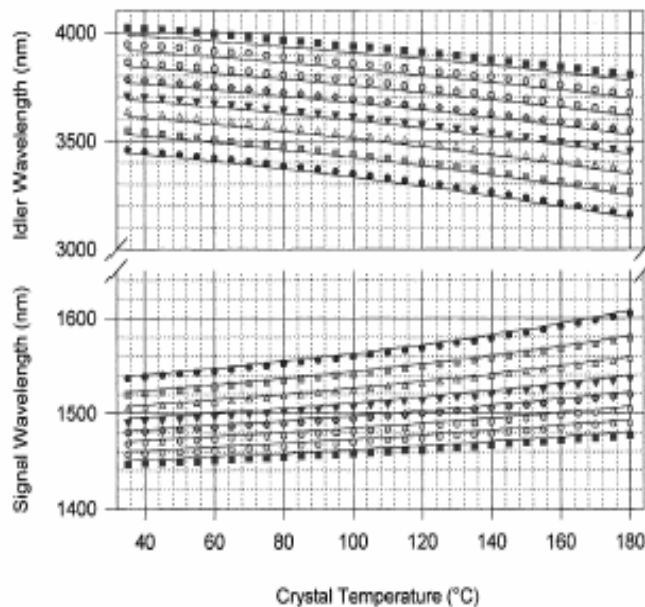
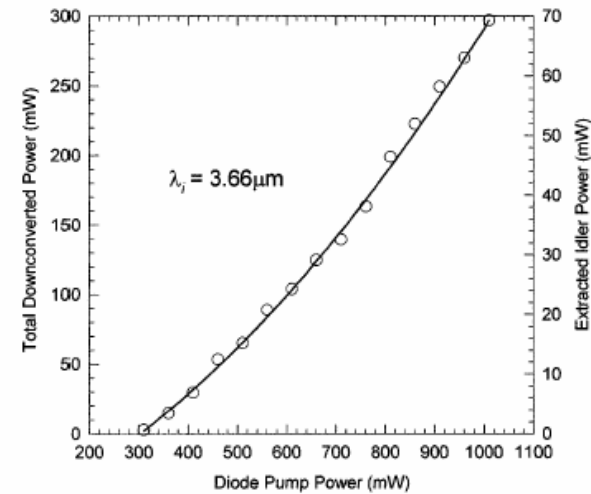
Fiber-Laser-Pumped High-Power CW OPO



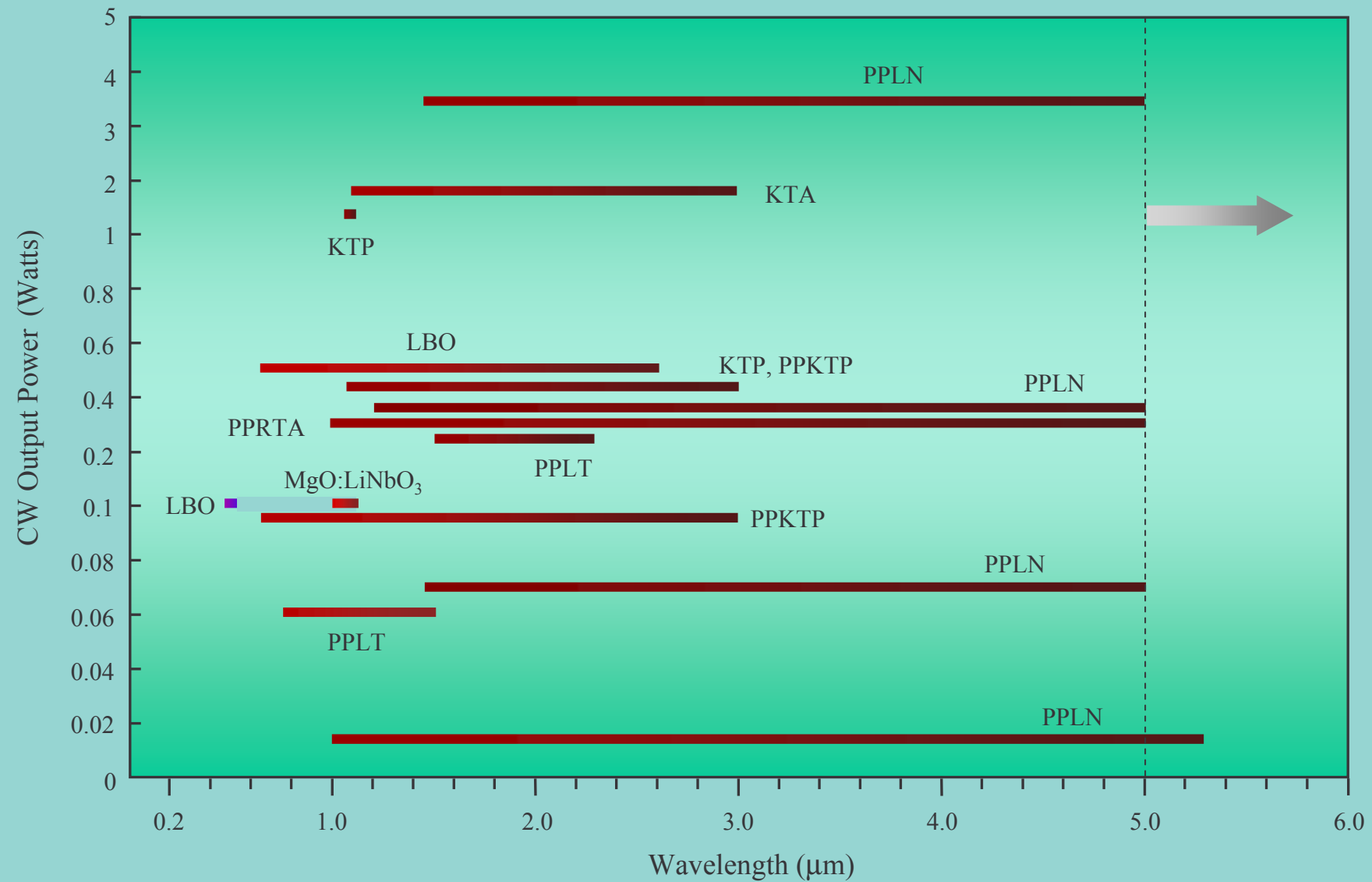
Miniature CW Intracavity OPO



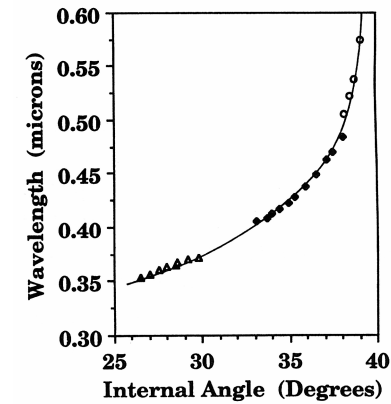
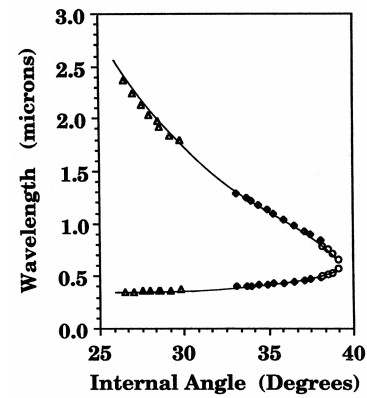
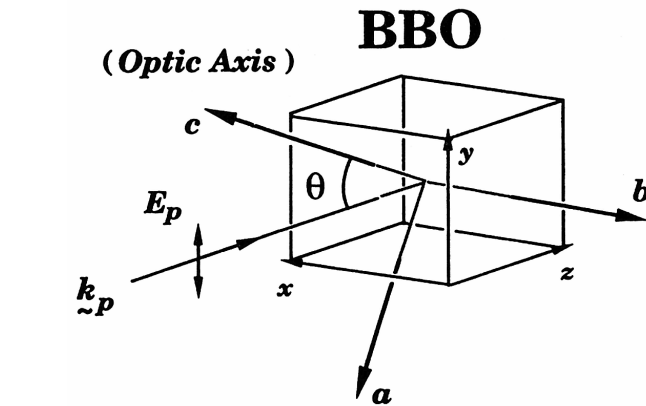
- $P_{th} = 300$ mW (diode power)
- $P_{idler} \sim 70$ mW (1 W diode power)
- $\lambda_{idler} \sim 3.1$ -4.1 μm



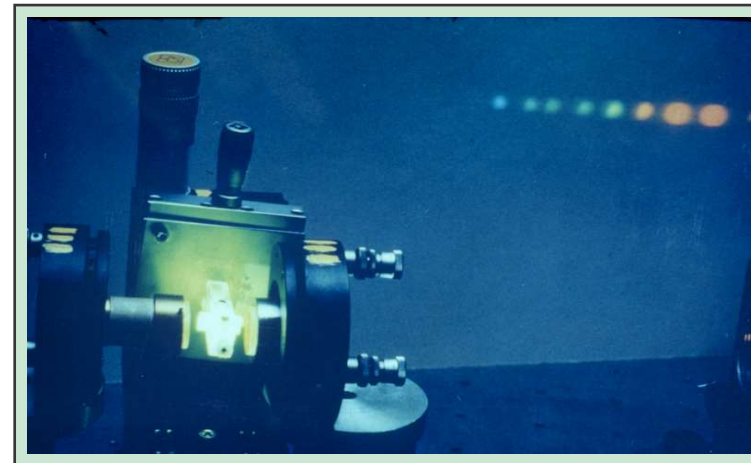
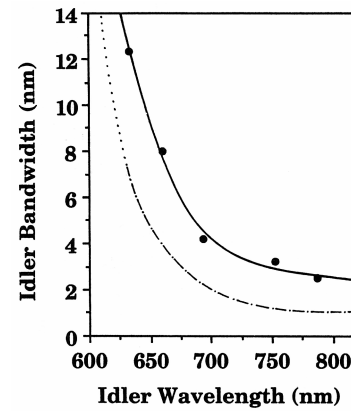
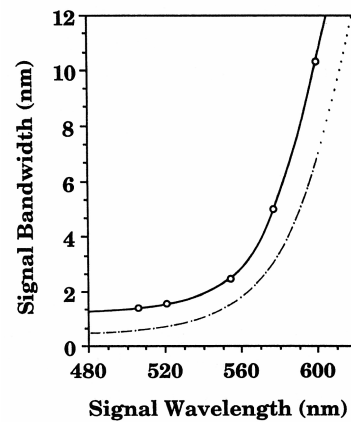
CW OPOs



Nanosecond OPOs



Tuning Range: 0.35-2.4 μm



Commercial System:

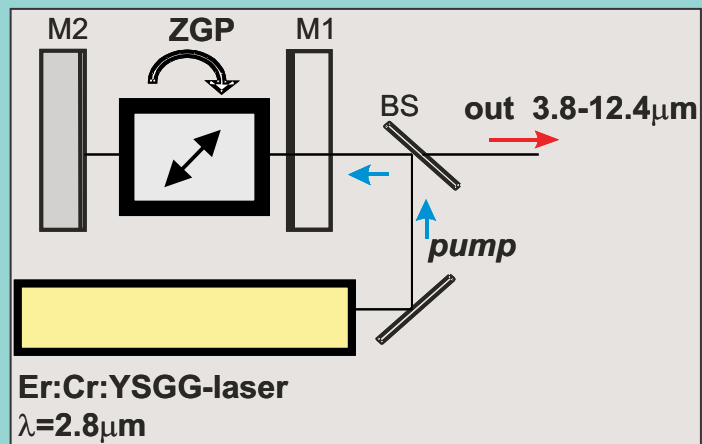


MOPO Series Optical Parametric Oscillator
MOPO-HF

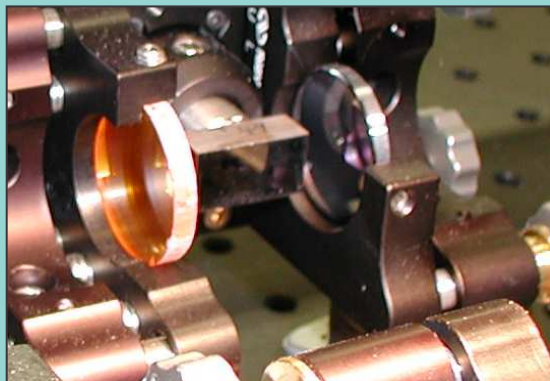
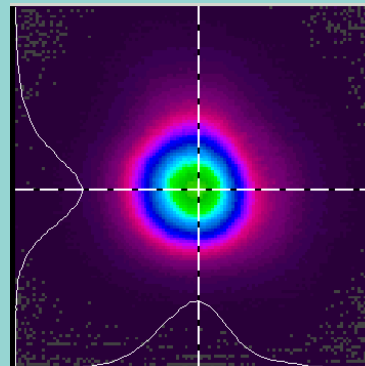
Pulsed Mid-IR OPO (4-12 μm)

Erbium (2.8 μm) laser pumped ZGP OPO

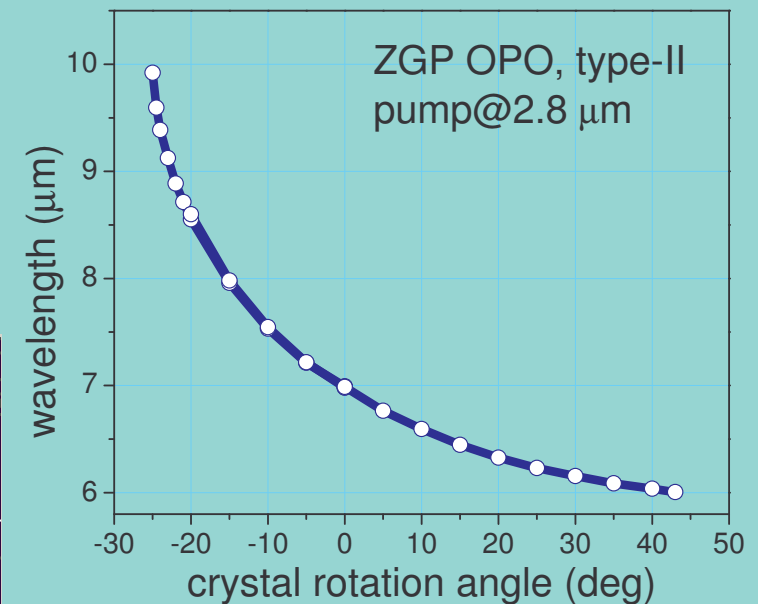
Pump: 2.8 μm , 3 mJ, 100ns, 25 Hz



Far Field
FWHM 3.6 mrad
 $\lambda=7\mu\text{m}$



Tuning curve



Idler tuning range: 3.8-12.4 μm

Linewidth: 1- 2 cm^{-1}

Quantum efficiency: 40-50 %

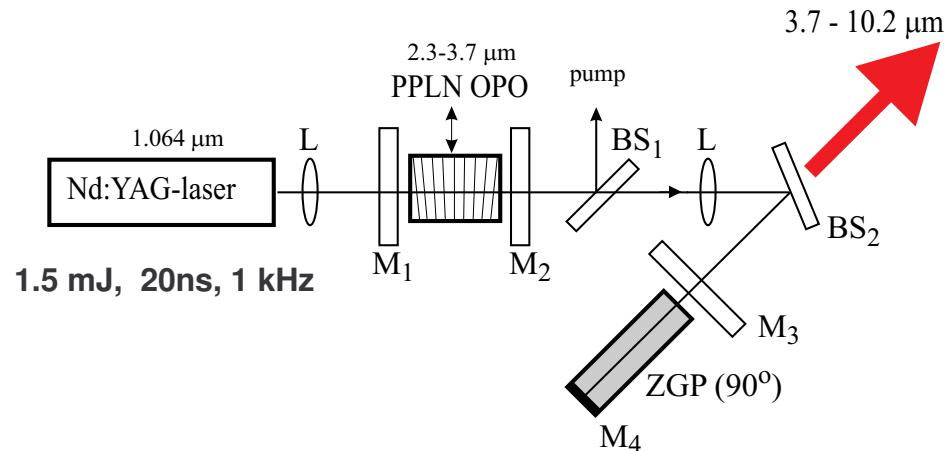
Pulse duration: 70 ns

Beam quality: $M^2 = 1.5$

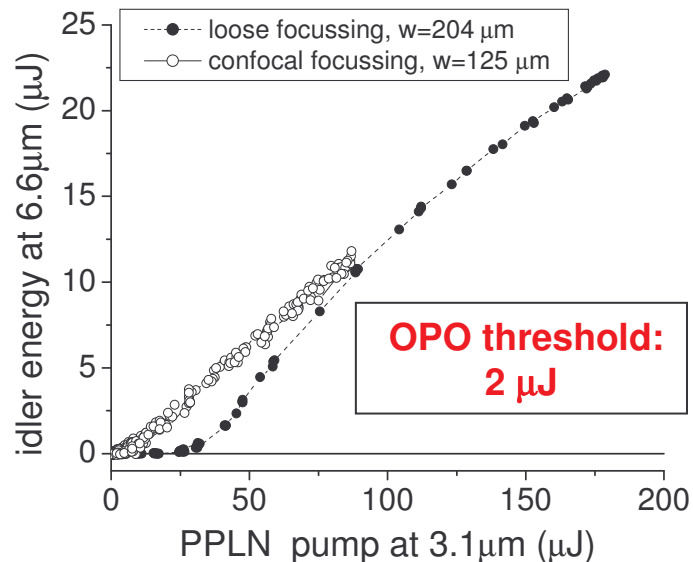
Rep. Rate: 25 Hz

Pulsed Mid-IR OPO (4-10 μm)

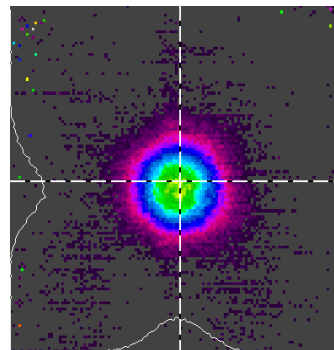
Compact noncritically phase-matched cascaded PPLN-ZGP OPO



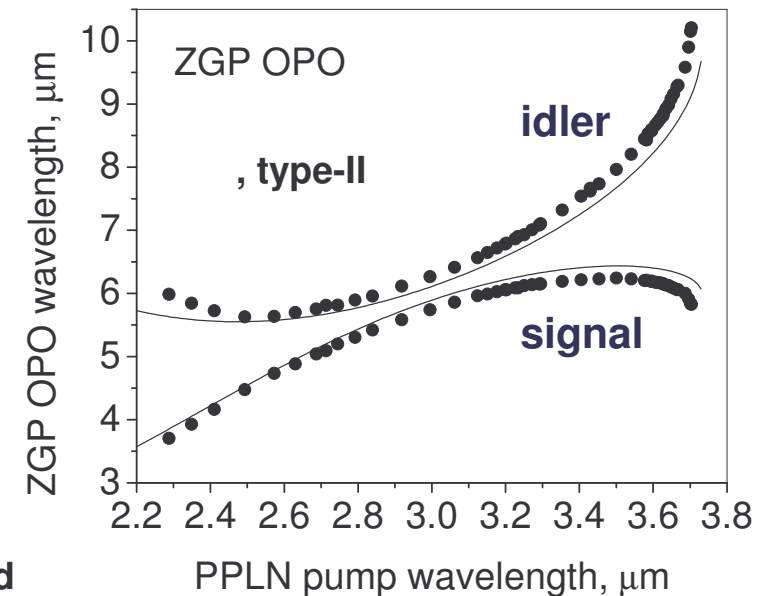
Energy curve



Far Field
FWHM 8.3 mrad
 $\lambda = 6 \mu\text{m}$

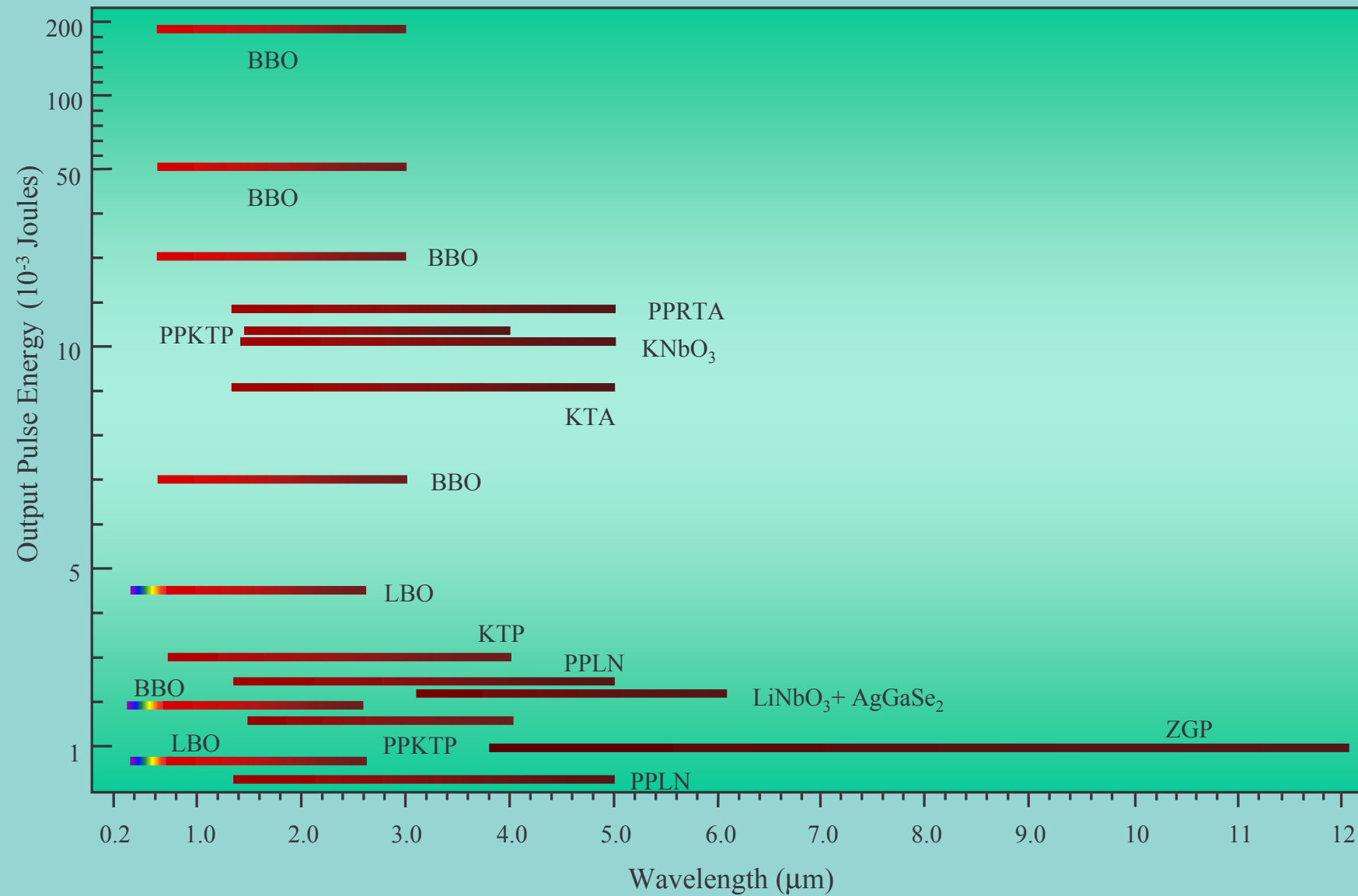


Tuning curves ZGP 90-deg

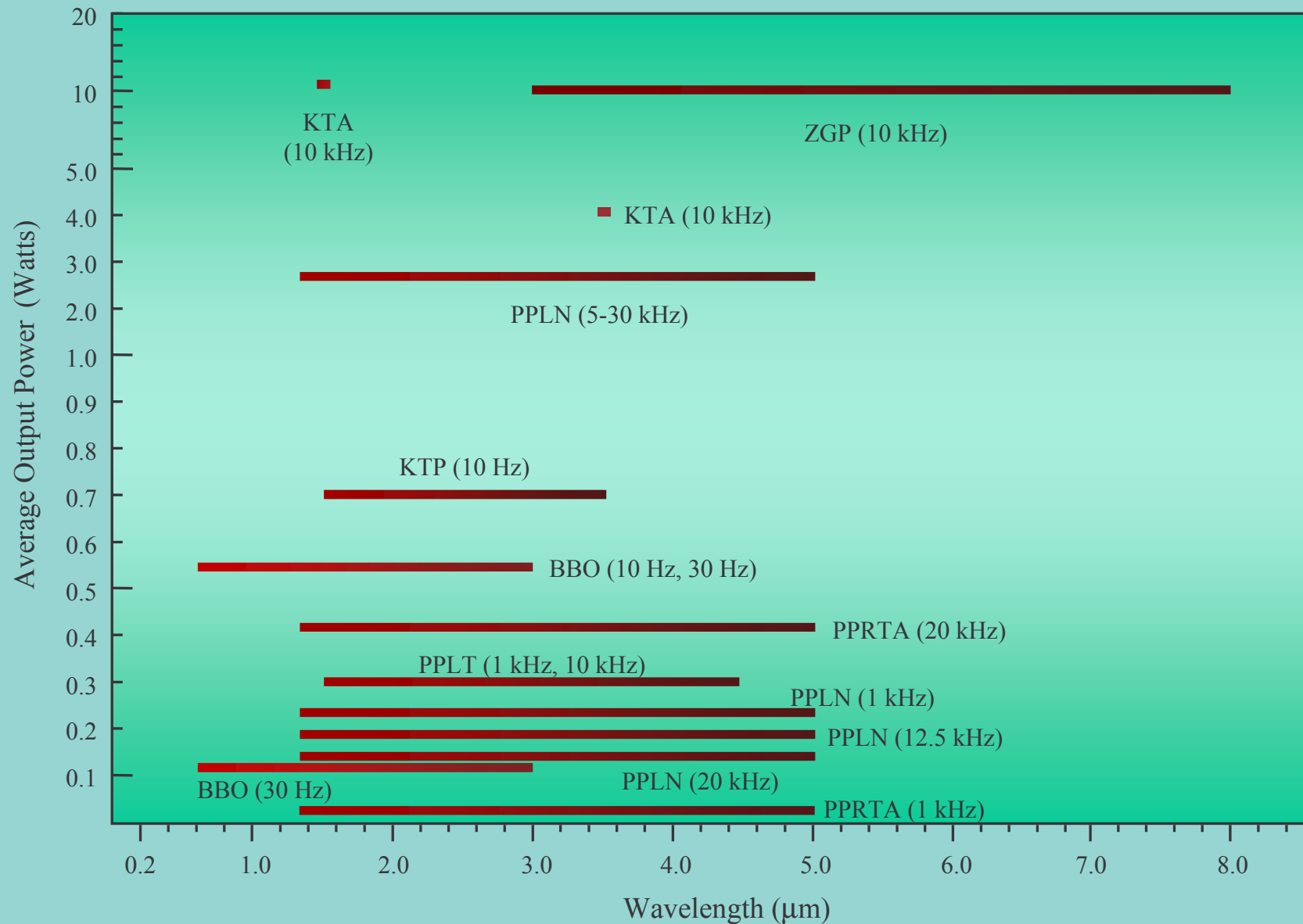


Tuning range: 3.7-10.2 μm
Linewidth: $\sim 5 \text{ cm}^{-1}$
ZGP OPO quantum efficiency: 30 %
Pulse duration: 20 ns
Beam quality: $M^2 = 1.75$
Energy stability: 2%
Rep. Rate: 100Hz - 10 kHz

Pulsed ns OPOs



Pulsed OPOs: High-repetition-rate



OPOs Advantages

- Gamma-ray generation through laser backscattering
- Tunability control of photon energy on either side of the maximum gamma-ray energy, $E_\gamma(\text{max})=37.5$ MeV. Useful for the experimental verification of theoretical calculations near $E_\gamma(\text{max})$, which will be of interest for some studies.
- Longer mid-IR wavelengths $\longrightarrow$ lower photon energies $\longrightarrow$ higher gamma-ray intensities (at lower gamma-ray energies) compared to ALL other laser backscattering facilities (except HIGS), which use Nd:YAG or argon-ion lasers.
(Makes LLS a particularly useful facility for lower-energy/higher-intensity gamma-ray experiments.)
- Large optical powers (several watts). Therefore, under similar operating parameters (σ_c , I_e , L , S), the OPO will be able to provide higher gamma-ray intensities.
- Excellent spatial quality (diffraction-limited optical beam, minimum divergence, suitable cross-section $\longrightarrow$ collimation, manipulation, and propagation over long distances with standard optical elements.
- Compact, all-solid-state design excellent output beam stability, with minimum variations in optical power, spatial beam quality, temporal stability, beam size and shape, and beam positioning over long distances.
- A new optical instrument, which has not been previously deployed in any other accelerator facilities throughout the world. Therefore, in addition to its usability, it will represent a world-first addition to such a facility, which will also enable novel scientific advances in high-energy accelerator physics.
- Indigenous to Spain.

CW OPO (1.5-5 μm)

OPO Design	Singly Resonant (PPLN)
Wavelength Coverage	1.5-5 μm
Photon Energy	0.82-0.25 eV
Output Power	2-10 W
Spatial Quality	$M^2 \sim 1$
Spatial Profile	Gaussian (TEM_{00})
Polarization	>99% Linear
Footprint	30 x 40 cm

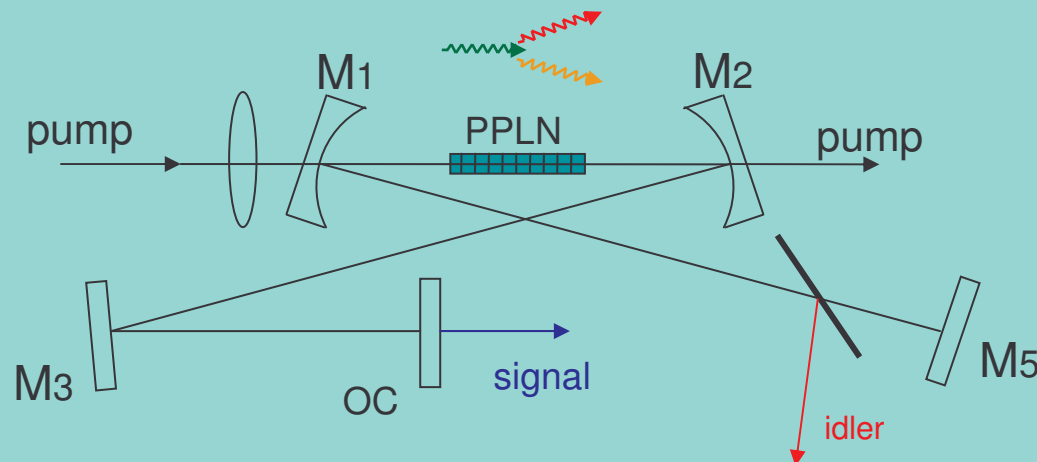
Pump Laser	Nd:YAG (cw)
Wavelength	1.064 μm
Output Power	30-100 Watts

Pulsed ns OPO (1.5-5 μm)

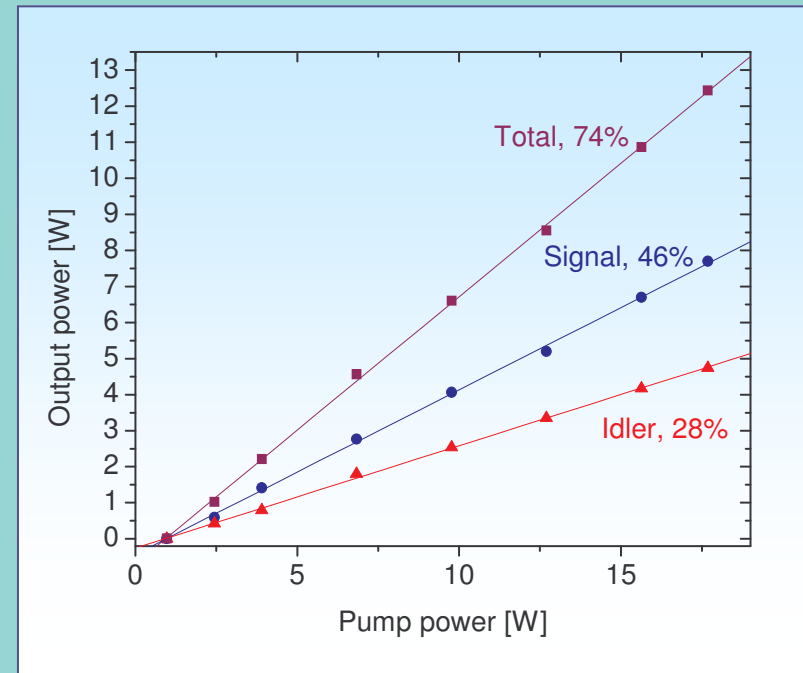
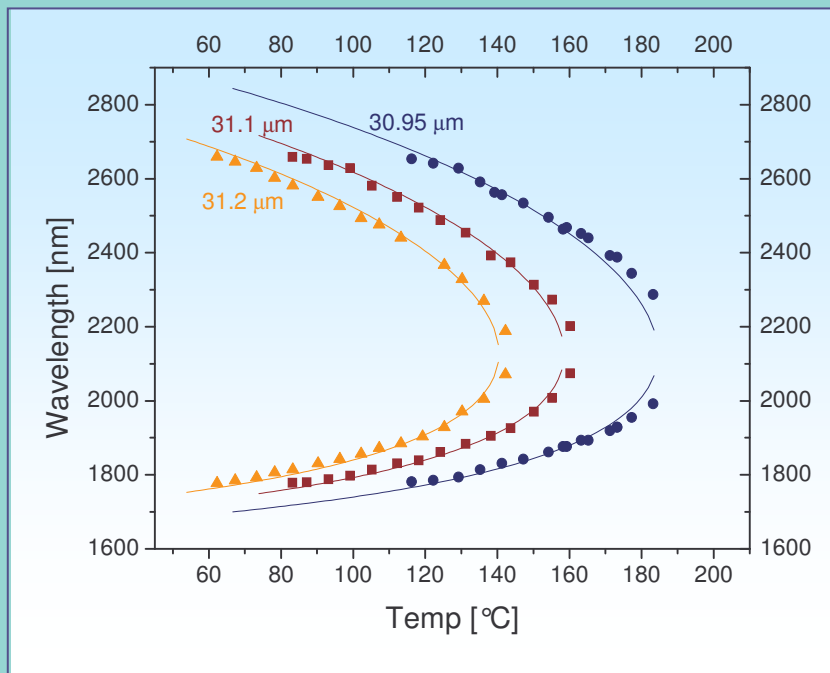
OPO Design	Singly Resonant (PPLN)
Wavelength Coverage	1.5-5 μm
Photon Energy	0.82-0.25 eV
Pulse Energy	>50 mJ
Pulse Duration	10-50 ns
Repetition Rate	1 Hz-100 Hz
Spatial Quality	$M^2 \sim 1$
Spatial Profile	Gaussian (TEM_{00})
Polarization	>99% Linear
Footprint	30x40 cm

Pump Laser	Nd:YAG (Q-switched)
Wavelength	1.064 μm
Pulse Energy	500-1000 mJ
Pulse Duration	10-50 ns
Repetition Rate	1Hz-100 Hz

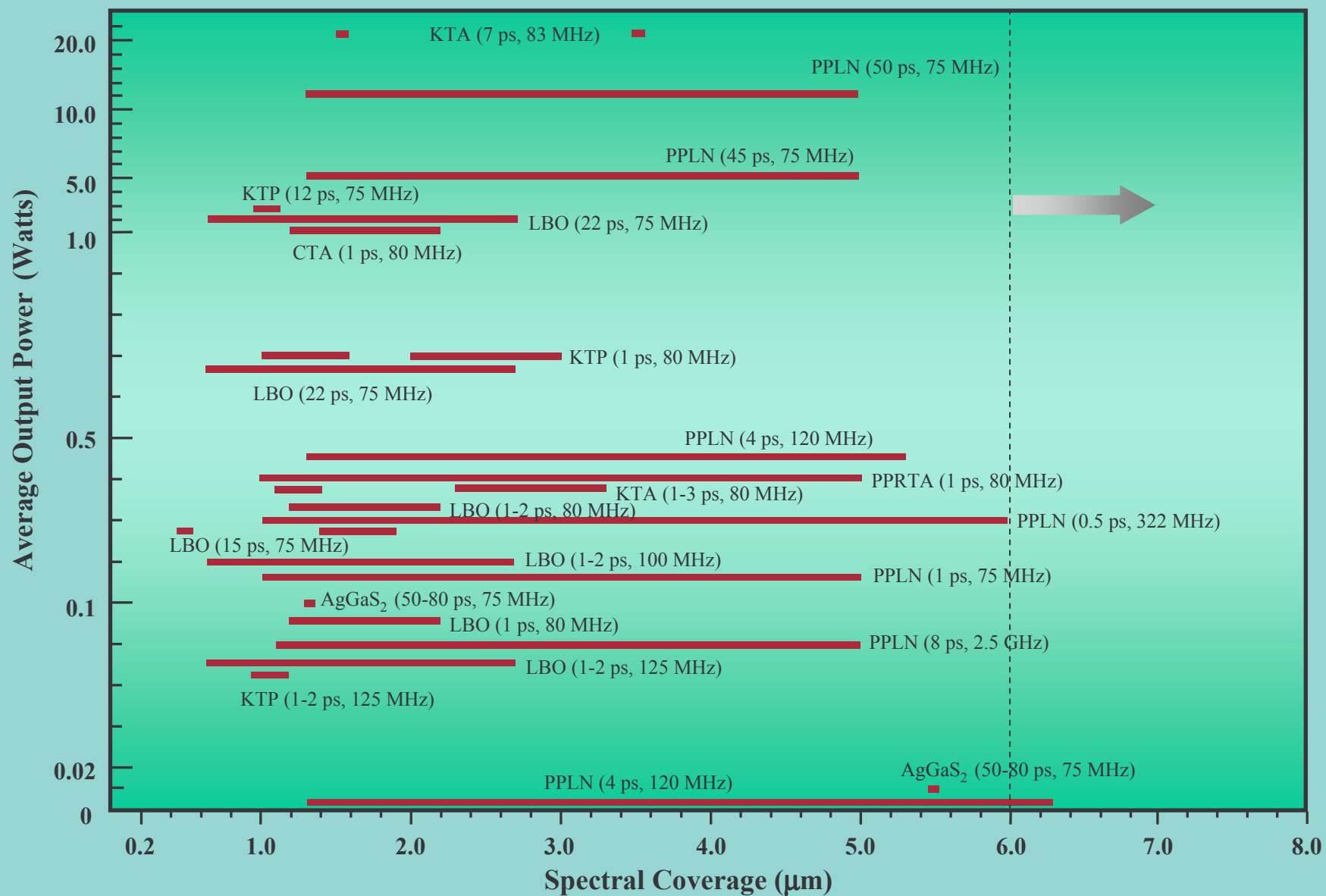
Picosecond OPO: High-Power Generation



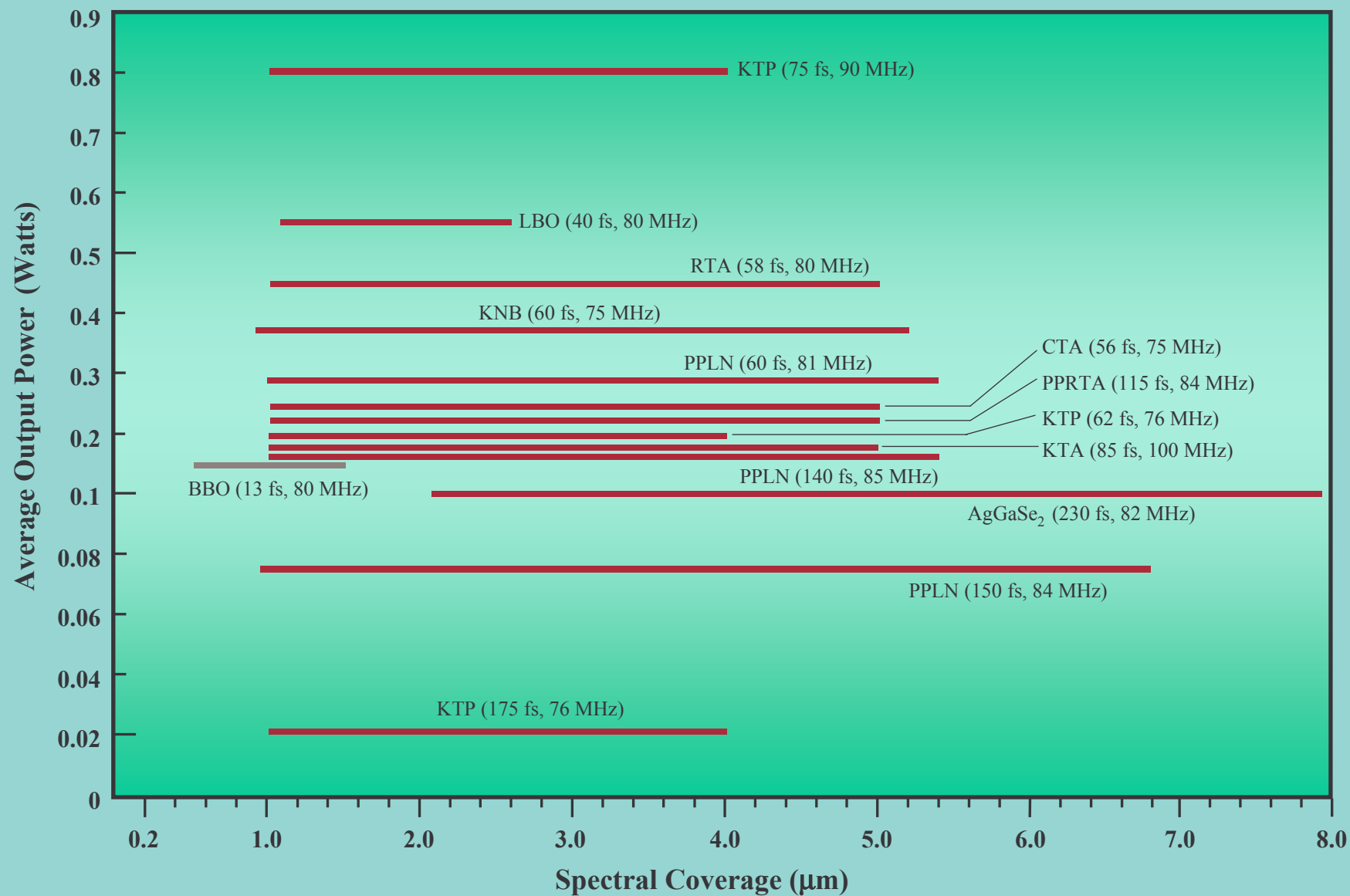
- 8 W signal (1.85 μm) for 17.7 W pump
- Total 12.4 W signal & idler



Picosecond OPOs



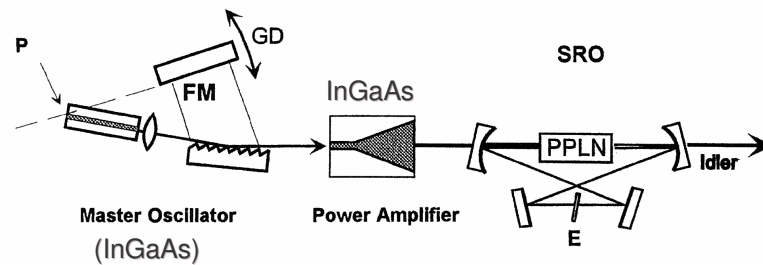
Femtosecond OPOs



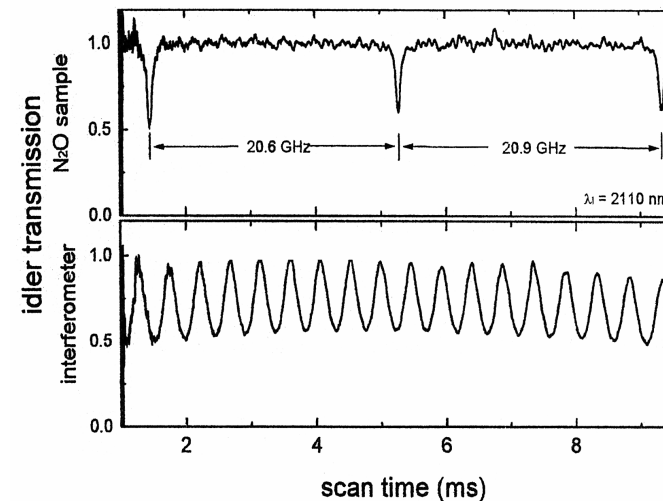
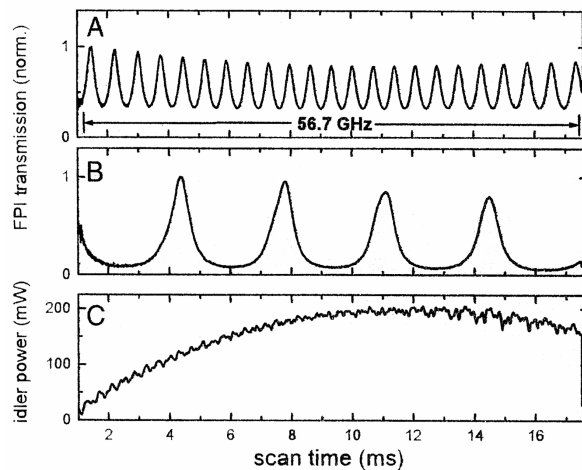
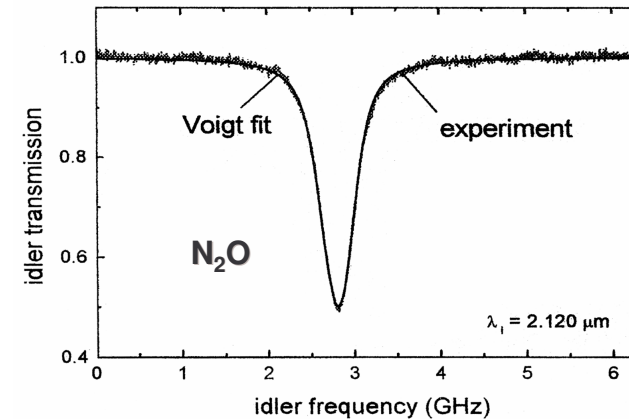
Some Applications!

Direct-Diode-Pumped CW SRO

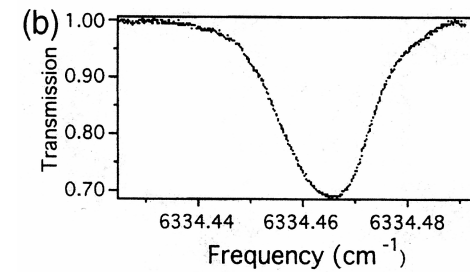
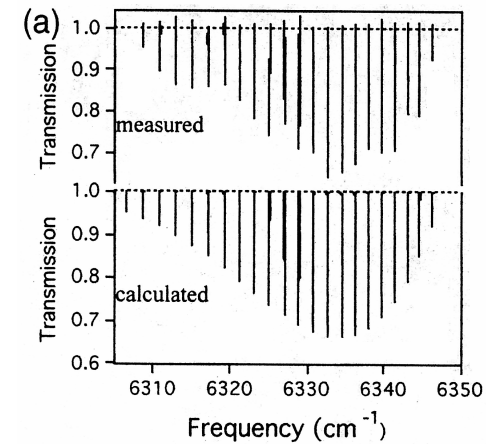
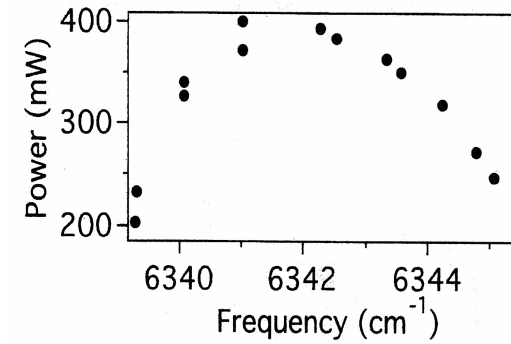
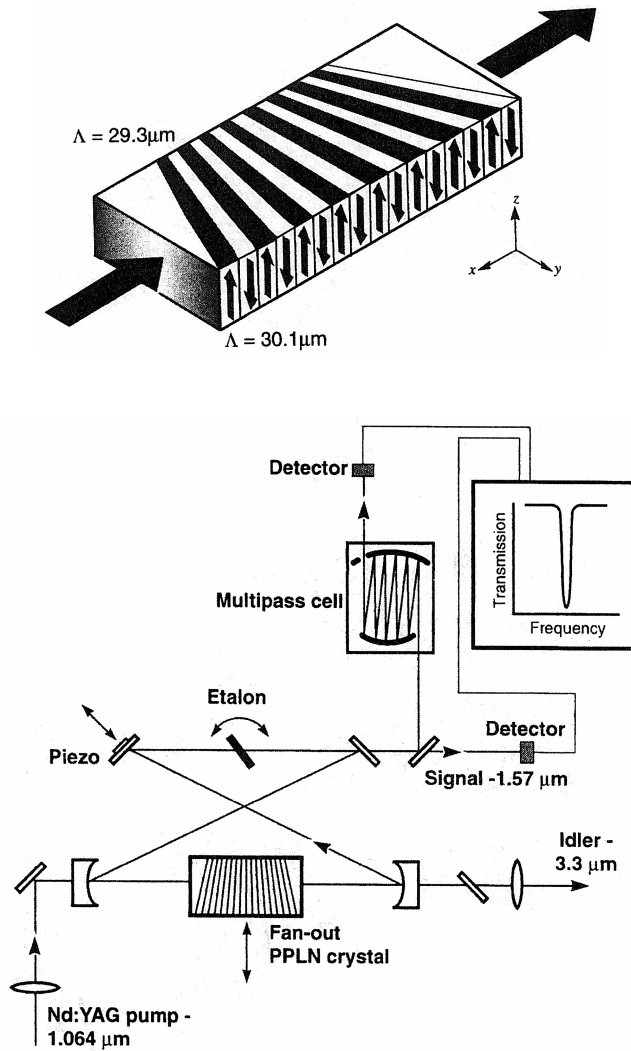
- 2.5 W @ 925 nm
- $\Delta\nu \sim 4$ MHz
- 60 GHz continuous tuning



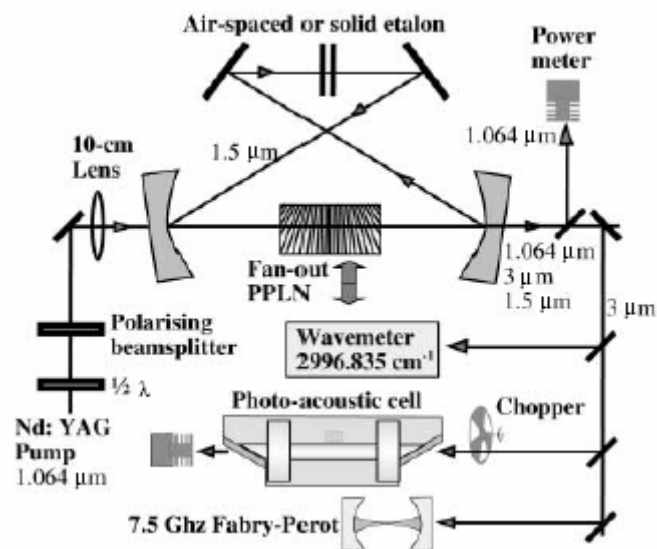
- 200 mW idler output
- 2.01-2.19 μm idler tuning
- 56 GHz continuous tuning



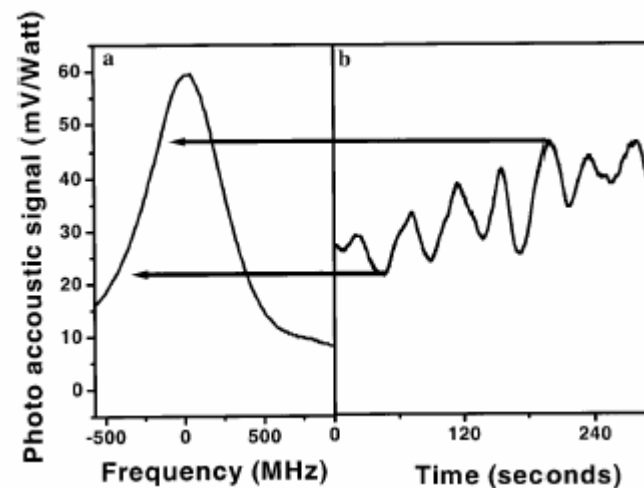
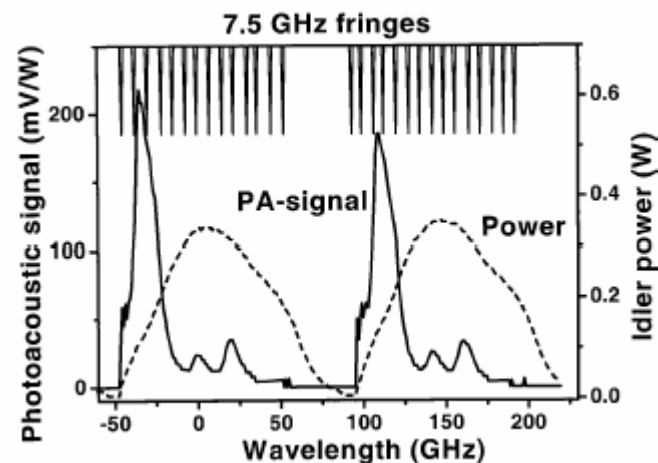
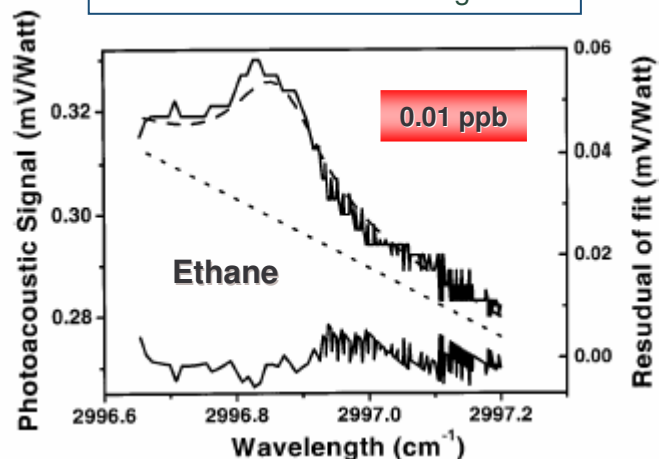
PPLN CW SRO



CW SRO: Photoacoustic Spectroscopy



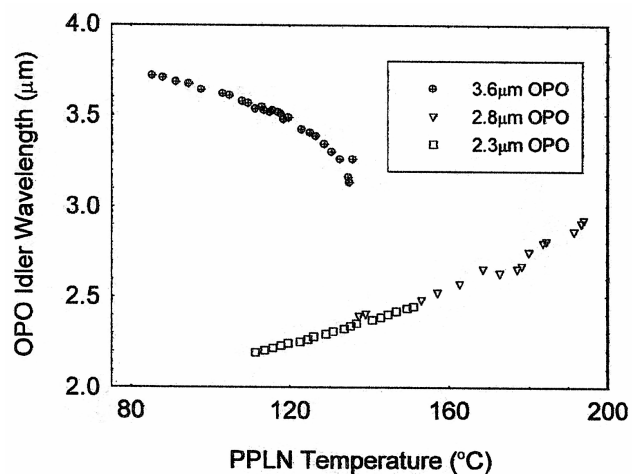
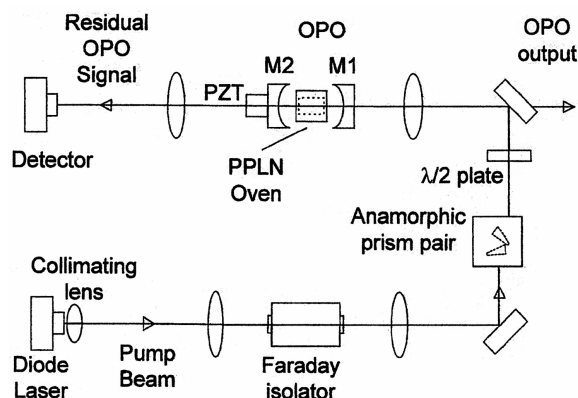
- 1.5 W idler output (10 W pump)
- 3.0-3.8 μm idler tuning
- 100 GHz mode-hop-tuning
- 24 GHz continuous tuning



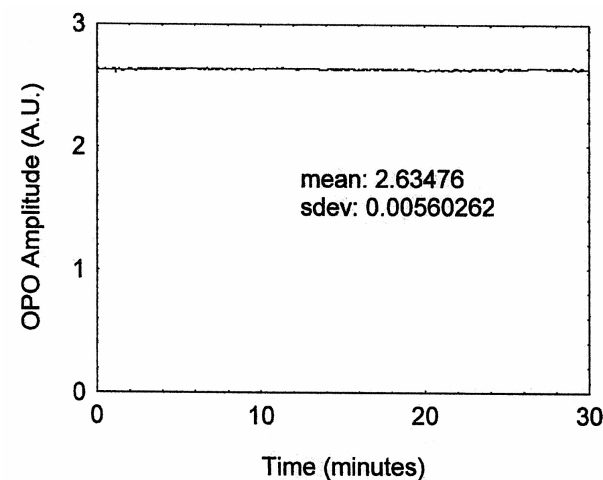
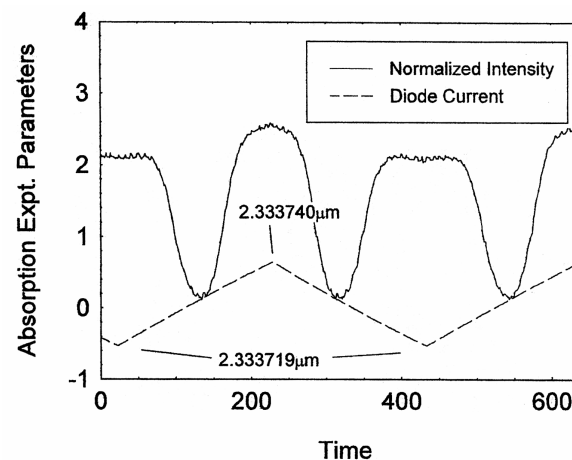
$\Delta\nu_{\text{drift}} < 200 \text{ MHz over } 300 \text{ s}$
($< 3 \text{ MHz over } 1 \text{ s}$)

Diode-Pumped CW DRO: Spectroscopy

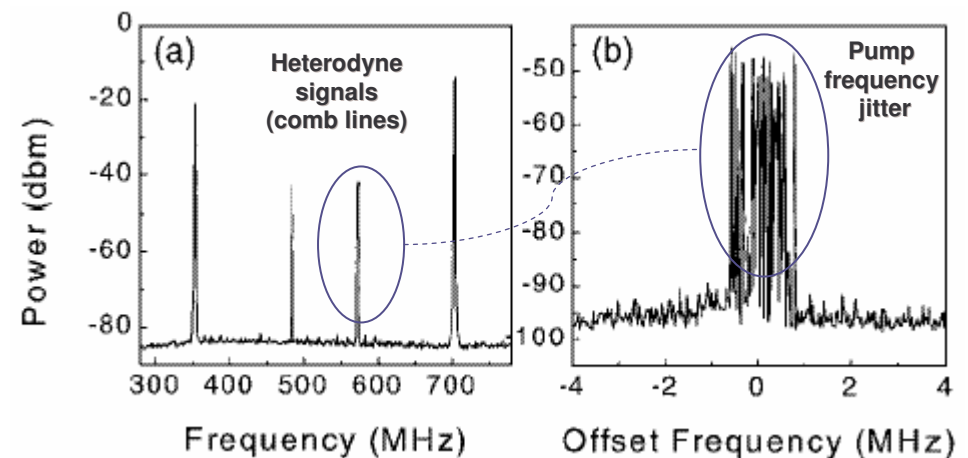
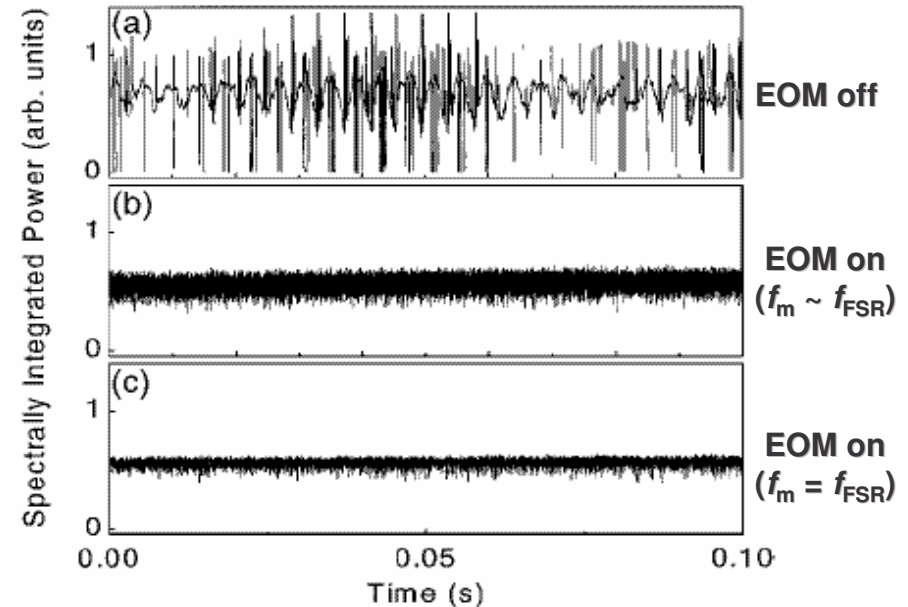
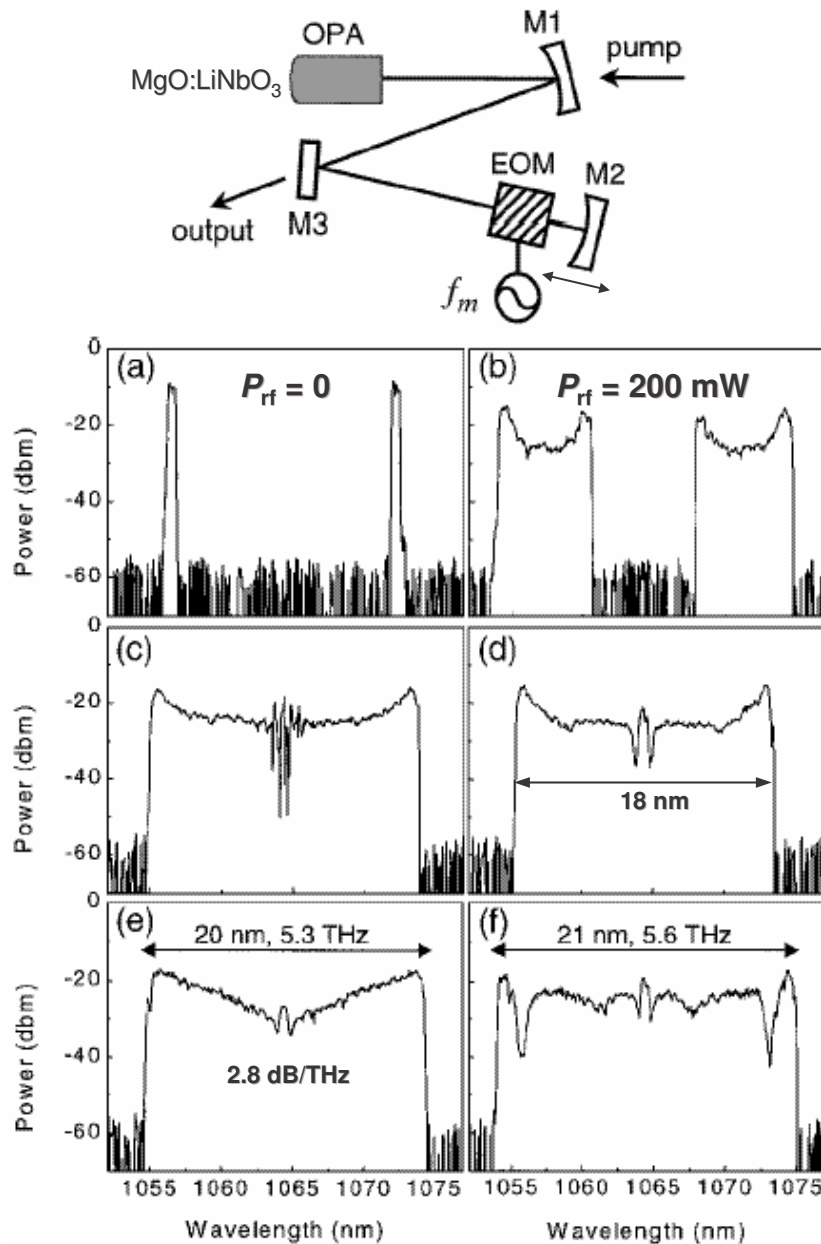
- 18 mW idler output
- 2.2-3.7 μm idler tuning
- 40 GHz continuous tuning
- 20 MHz linewidth



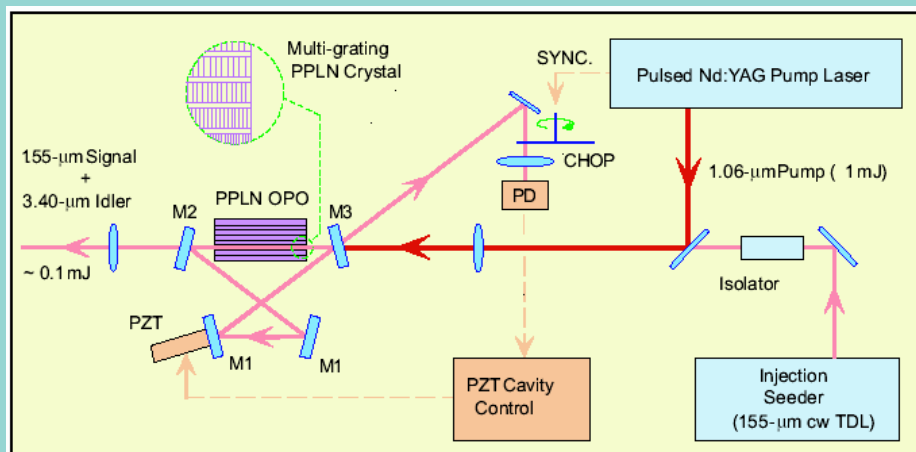
Continuous Tuning through
diode laser pump tuning



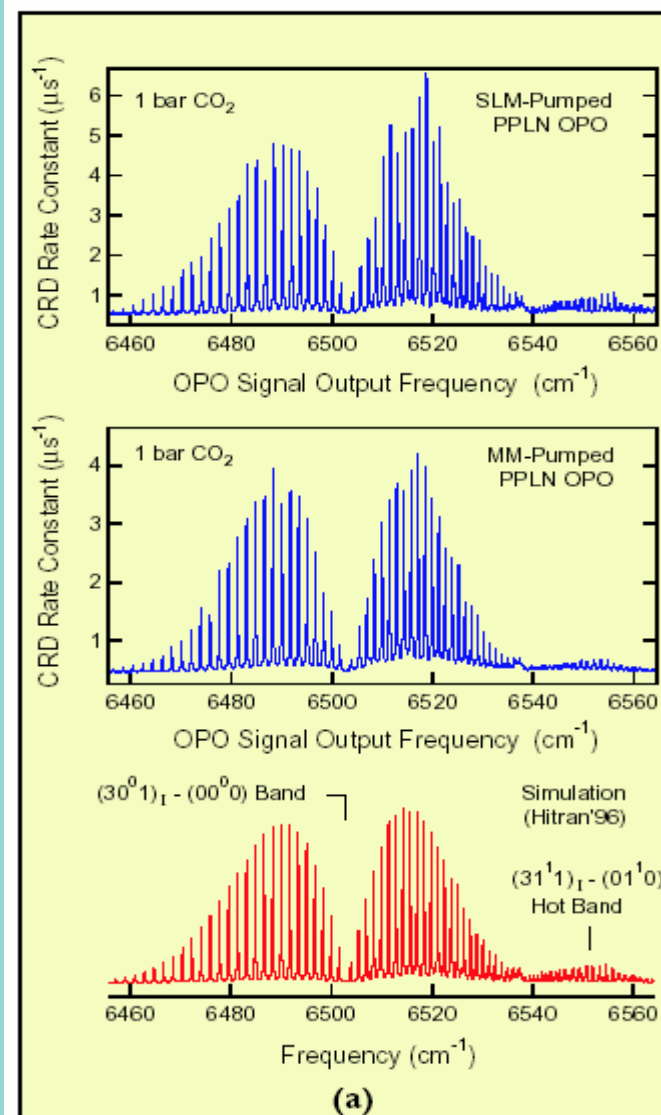
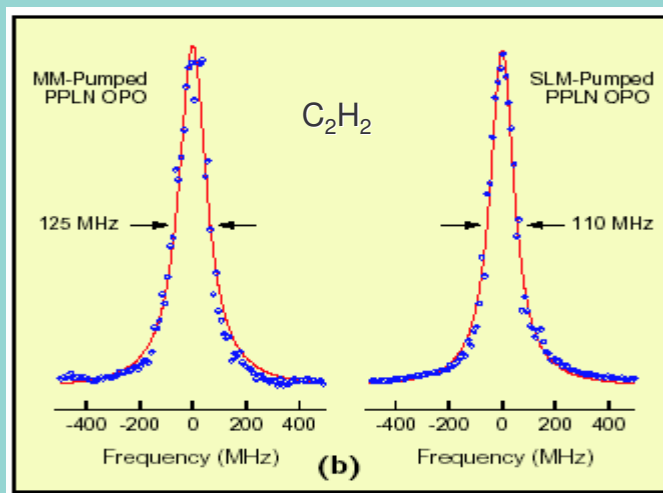
CW DRO: Frequency Comb Generation



Nanosecond SRO: Cavity Ring-down Spectroscopy



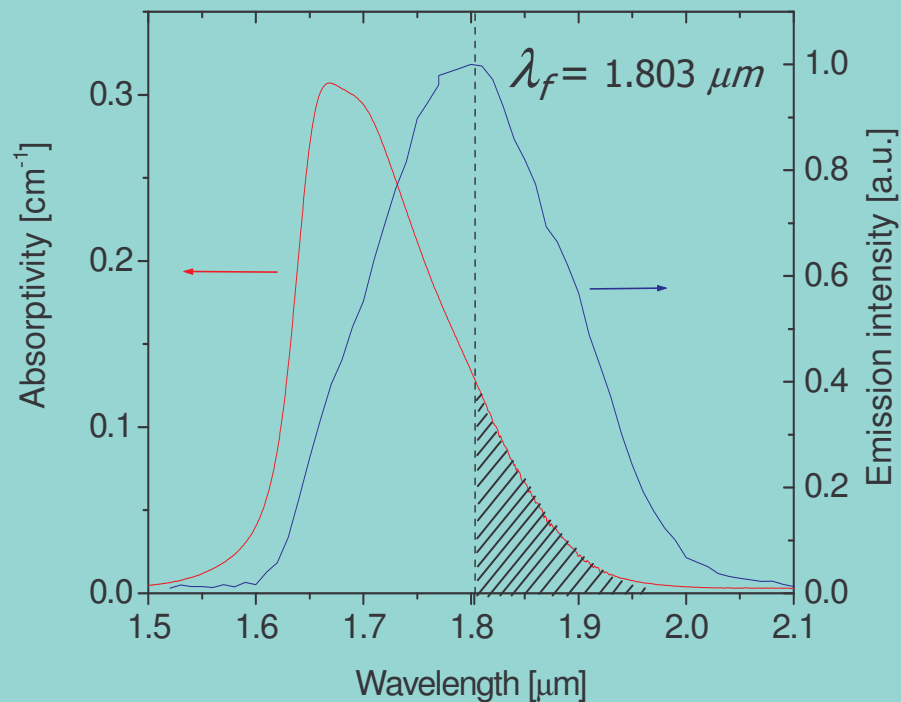
- 0.1 mJ signal pulse energy
- 1.5, 3.5 μm (signal, idler)
- 250 cm^{-1} continuous tuning
- <120 MHz linewidth (8 ns pulses)



High-Power ps OPO - Application

Optical Refrigeration in Solids

1 wt% Tm³⁺:ZBLANP



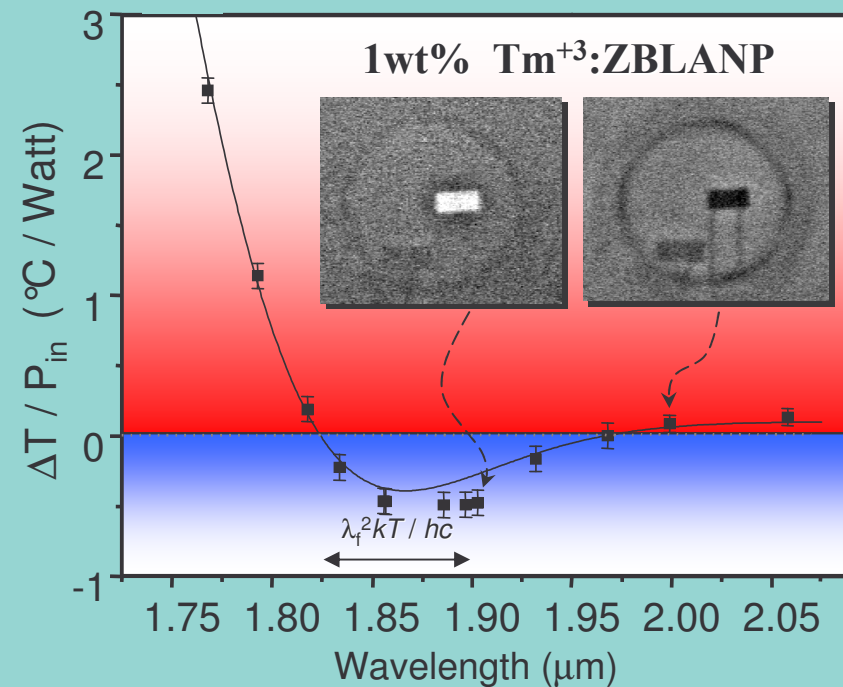
$$\frac{P_{cool}}{P_{absorbed}} = \frac{\lambda - \lambda_f}{\lambda_f}$$

3F_4 ————— 785 nm

3H_5 ————— 1190 nm

3H_4 ————— 1690 nm

3H_6



Atomic mercury flux monitoring using an optical parametric oscillator based lidar system

Mikael Sjöholm, Petter Weibring, Hans Edner and Sune Svanberg

Atomic Physics Division, Lund Institute of Technology, P.O. Box 118, 221 00 Lund, Sweden

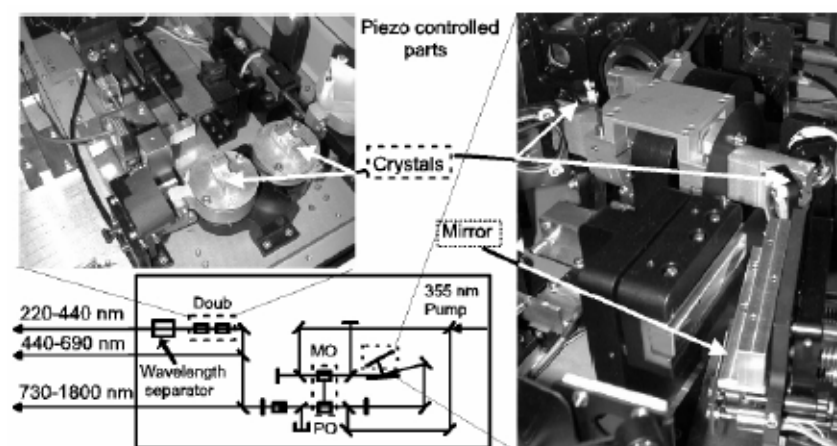


Fig. 2. Schematic overview of the master oscillator (MO) and power oscillator (PO) transmitter.



Fig. 1. The mobile lidar system in a field campaign in Rosignano Solvay, Italy.

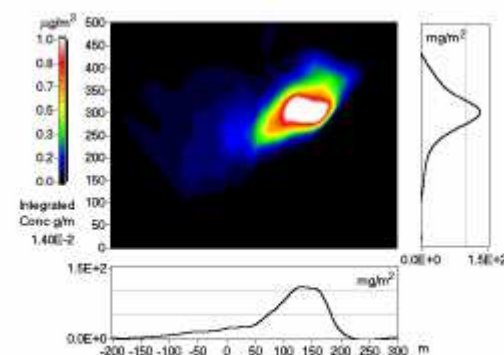
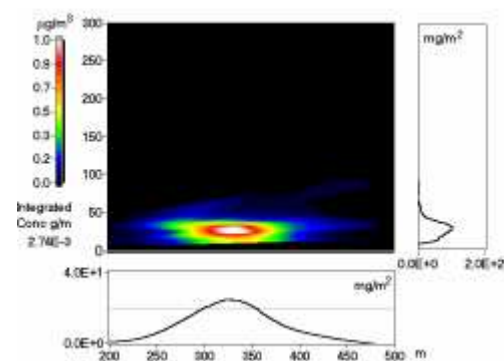


Fig. 3. (417 KB) Movie of horizontal concentration maps from the MCCA plant in Rosignano Solvay 2002-02-03, 12:11-12:38.



Optical Parametric Oscillators

***Flexible solid-state sources of light with unique
spectral and temporal versatility***

<i>CW</i>	→	<i>13 fs</i>
<i>1 Hz</i>	→	<i>30 GHz</i>
<i>1 mW</i>	→	<i>30 W</i>
<i>1 μJ</i>	→	<i>200 mJ</i>
<i>400 nm</i>	→	<i>12 μm</i>

- **Wavelength barrier $> 5 \mu\text{m}$ (cw/ps/fs OPOs):**
Alternative QPM (e.g. GaAs) and BPM Materials (e.g. ZnGeP_2 , LiInS_2 , etc.)
Novel Device Architectures (e.g. cascade, intracavity, etc.)
- **Wavelength barrier $< 1 \mu\text{m}$ (cw OPOs):**
Novel visible laser pump sources (e.g. GaN diodes)
- **Power barrier $>$ few Watts (cw/fs OPOs):**
High-power pump sources (e.g. fiber, crystalline, etc.)
- **Novel Devices:**
Integrated Microstructures, waveguides (GaAs, PPLN)
- **New Application Areas:**
Biophotonics, IR Imaging, Frequency Metrology, etc.



Many New Challenges / Opportunities Remain:

Devices

Applications

Materials